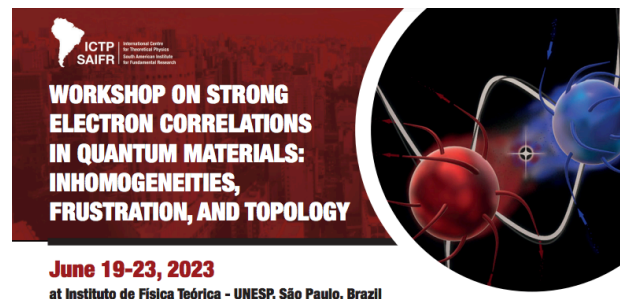


# Geometrical effects on thermopower properties of correlated electrons

Thereza Paiva



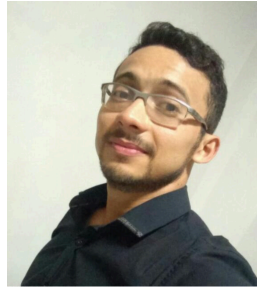
# Collaborators



Willdauany de F Silva



Natanael C Costa



Maykon V Araujo



Sayantan Roy



Abhisek Samanta



Nandini Trivedi



**ArXiv:2303.16291**

**Effects of lattice geometry on thermopower properties of the repulsive Hubbard model**

Willdauany C. de Freitas Silva,<sup>1</sup> Maykon V. Araujo,<sup>2</sup> Sayantan Roy,<sup>3</sup> Abhisek Samanta,<sup>3</sup> Natanael de C. Costa,<sup>1</sup> Nandini Trivedi,<sup>3</sup> and Thereza Paiva<sup>1</sup>

<sup>1</sup>*Instituto de Física, Universidade Federal do Rio de Janeiro, Rio de Janeiro, RJ 21941-972, Brazil*

<sup>2</sup>*Departamento de Física, Universidade Federal do Piauí, 64049-550 Teresina PI, Brazil*

<sup>3</sup>*Department of Physics, The Ohio State University, Columbus OH 43210, USA*

# Summary

Thermoelectric materials  
and thermopower

Hubbard Model

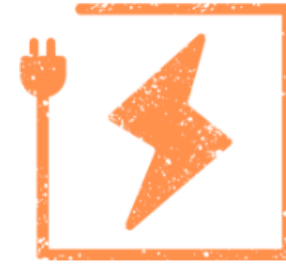
Seebeck coefficient and Power factor

Conclusions

# Thermoelectric effects



Thermal energy



Electric energy

Thermoelectric materials: induced voltage in the presence of temperature gradient

# Thermoelectric materials

Figure of merit

$$ZT = \frac{S^2 \sigma T}{\kappa}$$

$S$  → Thermopower or Seebeck coefficient  
Conversion efficiency from  
thermal to electrical energy

$\sigma$  → Conductivity

$\kappa$  → Thermal conductivity

G. Mahan, B. Sales and J. Sharp, Physics Today 50, 3, 42 (1997)

# Thermoelectric materials

Figure of merit

$$ZT = \frac{S^2 \sigma T}{\kappa}$$

$S$  → Thermopower or Seebeck coefficient  
Conversion efficiency from  
thermal to electrical energy

$\sigma$  → Conductivity

$\kappa$  → Thermal conductivity

Metals



Low  $S$

Insulators



Low  $\sigma$

Doped insulators



Best choice?

# Thermoelectric materials

Figure of merit

$$ZT = \frac{S^2 \sigma T}{\kappa}$$

$S$  → Thermopower or Seebeck coefficient  
Conversion efficiency from  
thermal to electrical energy

$\sigma$  → Conductivity

$\kappa$  → Thermal conductivity

Power Factor

$$PF = S^2 \sigma$$

# Correlated materials



Large Seebeck coefficient

Wissgott et al PRB82 (10), Wissgott et al PRB 84 (11)

Cuprates



Sign change of Seebeck coefficient  
near optimum doping

Obertelli et al PRB 46 (92), Tallon et al PRB 51 (95)



How is the thermopower affected by geometry?

How is thermopower affected by correlations?

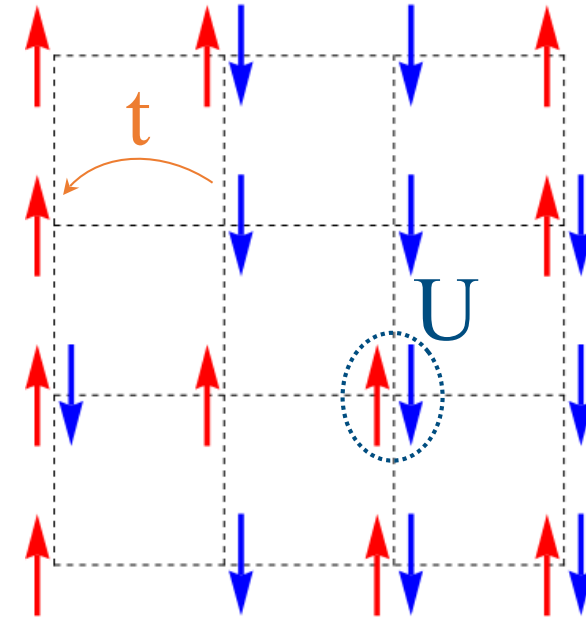
# Hubbard Model

$$\mathcal{H} = -\mathbf{t} \sum_{\langle i,j \rangle, \sigma} \left( \hat{c}_{i,\sigma}^\dagger \hat{c}_{j,\sigma} + h.c. \right) + \mathbf{U} \sum_i \left( \hat{n}_{i\uparrow} - \frac{1}{2} \right) \left( \hat{n}_{i\downarrow} - \frac{1}{2} \right) - \mu \hat{N}$$

Coulomb repulsion ( $U > 0$ )

Hopping ( $t$ )

chemical potential ( $\mu$ )



No known analytic solution in 2D

QMC to study the Hubbard Model on square, triangular and honeycomb lattices

# Some details on our QMC simulations



100 sites



144 sites



162 sites

Each run:

2000 warm up sweeps,  
5000 measurement sweeps

$$\Delta\tau < 0.1$$

$$0 \leq U \leq 10$$

Sweeps through density: 500 jobs for each  
temperature and interaction strength

# Non-interacting Density of states

Dispersion relations



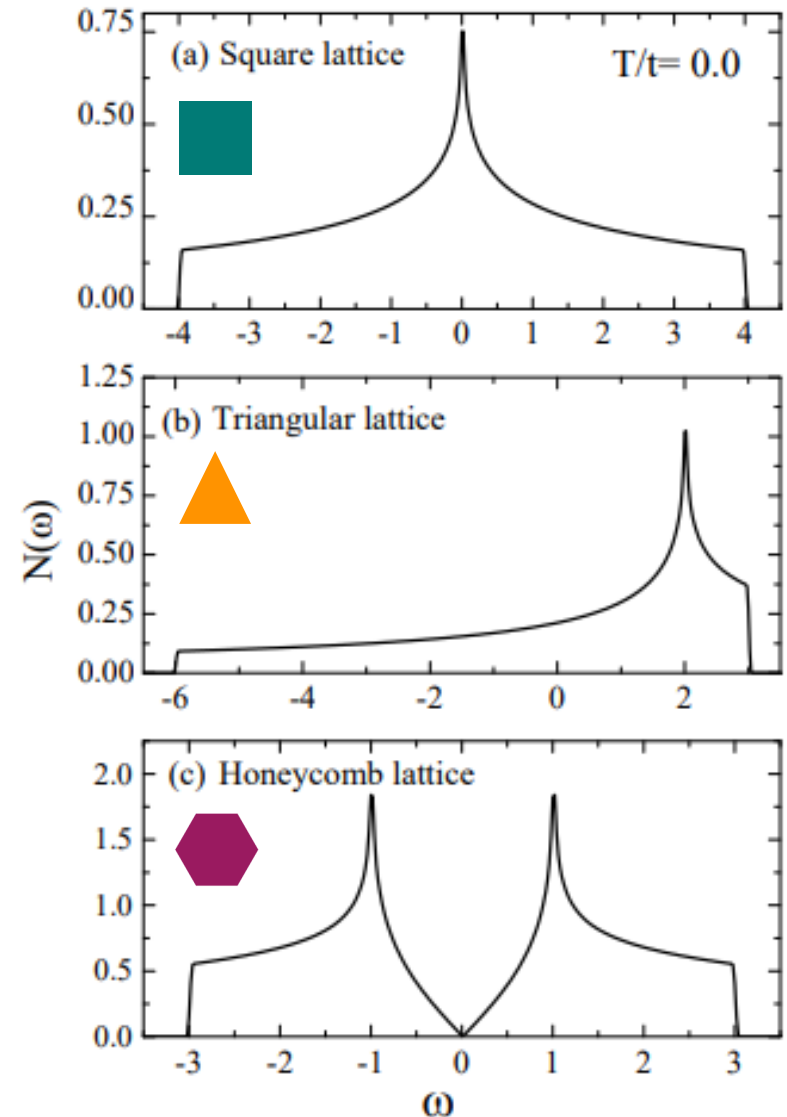
$$E(k) = -2t(\cos k_x + \cos k_y)$$



$$E(k) = -2t\left[\cos\left(\frac{k_x + \sqrt{3}k_y}{2}\right)\cos\left(\frac{k_x - \sqrt{3}k_y}{2}\right) + \cos(k_x)\right]$$



$$E_{\pm}(k) = \pm t\sqrt{3 + 2\cos(k_x) + 2\cos(k_y) + 2\cos(k_x + k_y)}$$

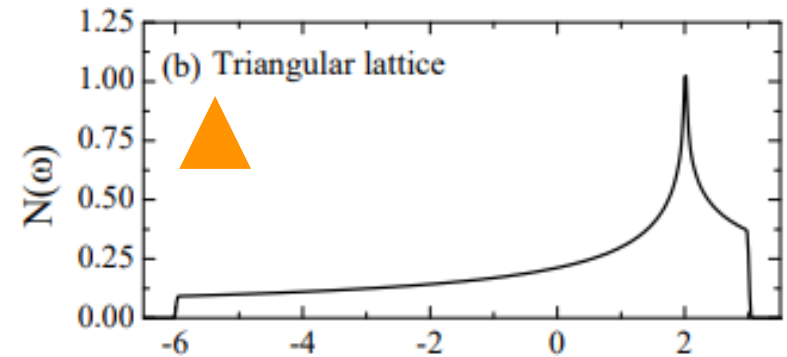
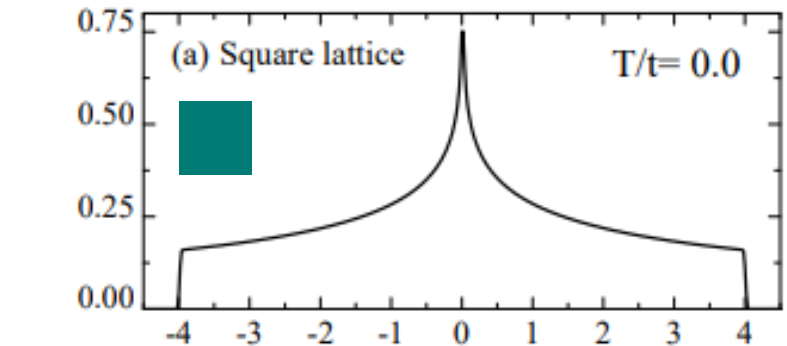


# Non-interacting Density of states

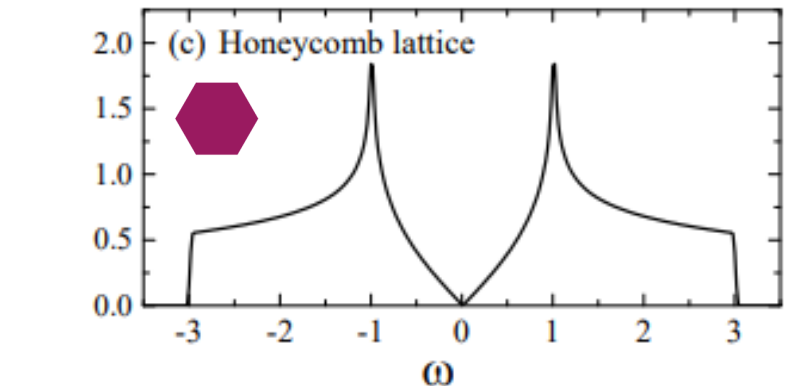
van Hove singularity



Particle-hole symmetry

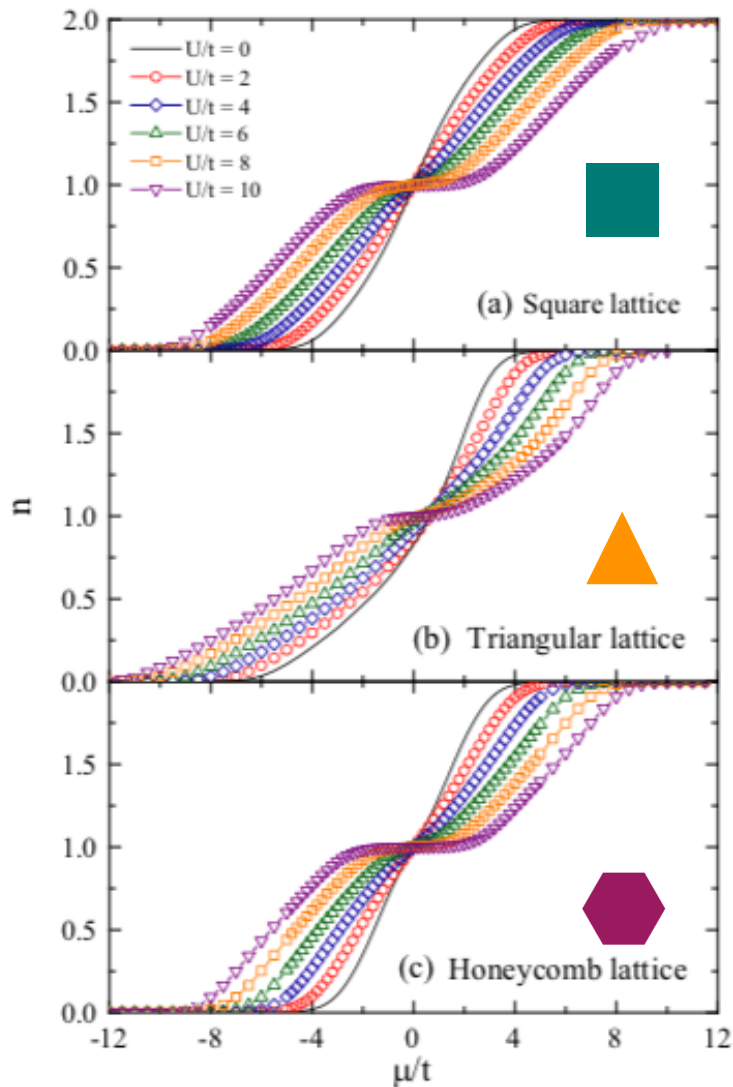


Particle-hole symmetry



# Density

$$T/t=0.5$$



$$n(-\mu) = 2 - n(\mu)$$



Particle-hole  
symmetry

$$n(-\mu) \neq 2 - n(\mu)$$



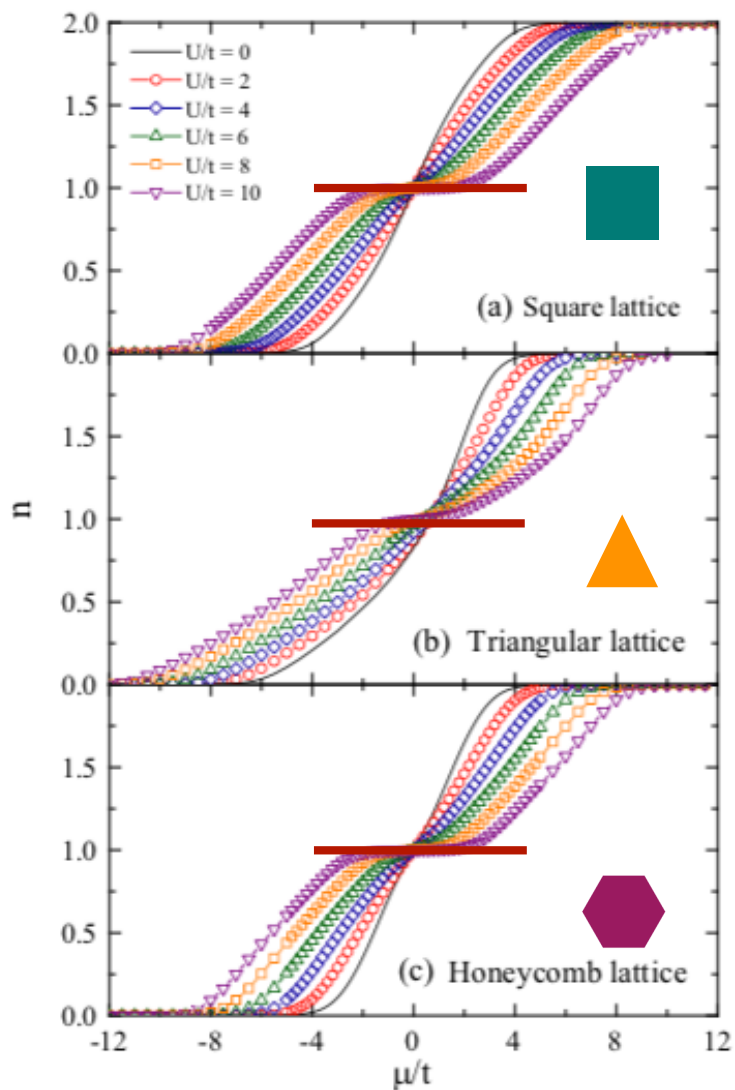
Non-bipartite

$$n(-\mu) = 2 - n(\mu)$$



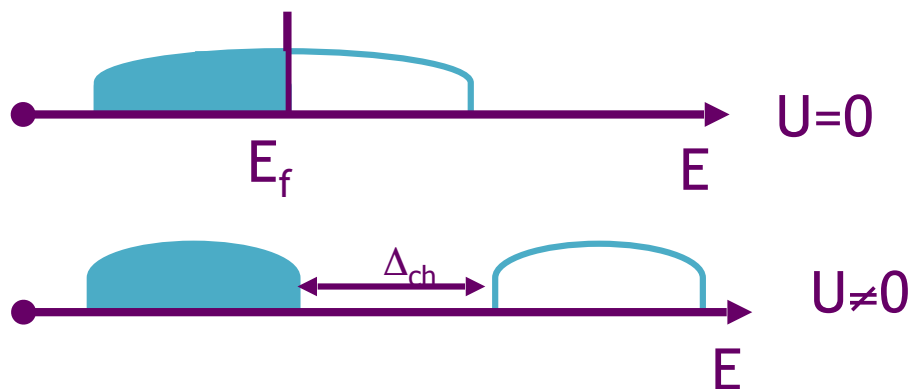
Particle-hole  
symmetry

# Density



$$T/t=0.5$$

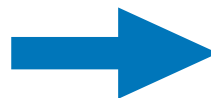
Mott transition



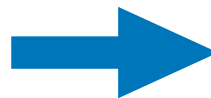
$$U/t > 0$$



$$U_c/t \approx 7 - 8$$



$$U_c/t \approx 3.8$$



Yoshioka PRL 09,  
Shirakawa PRB 17

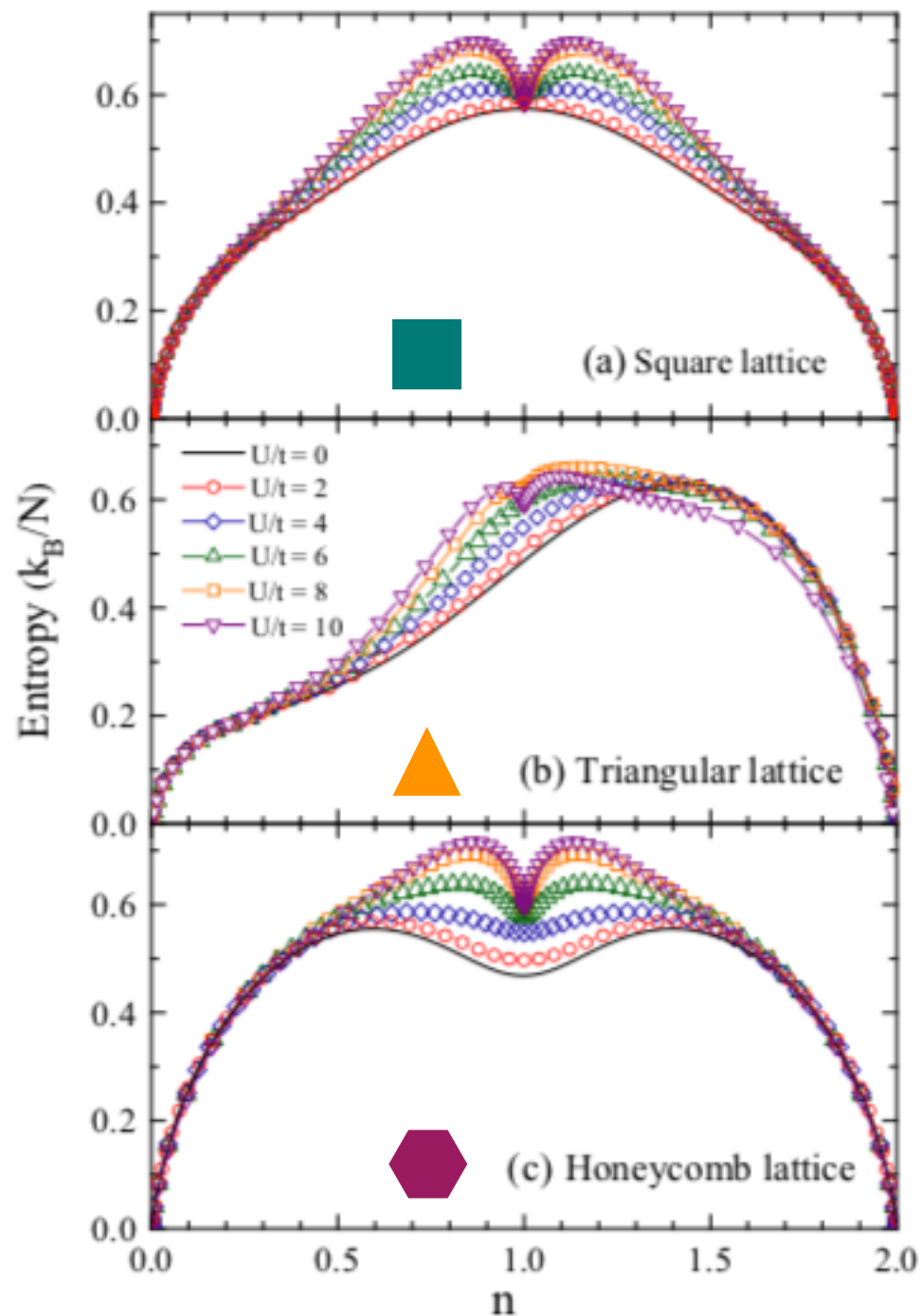
Otsuka PRX 16

# Entropy

$$s(\mu, T) = \int_{-\infty}^{\mu} d\mu \frac{\partial n}{\partial T} \Big|_{\mu}$$

In units of  $k_B$

$T/t=0.5$



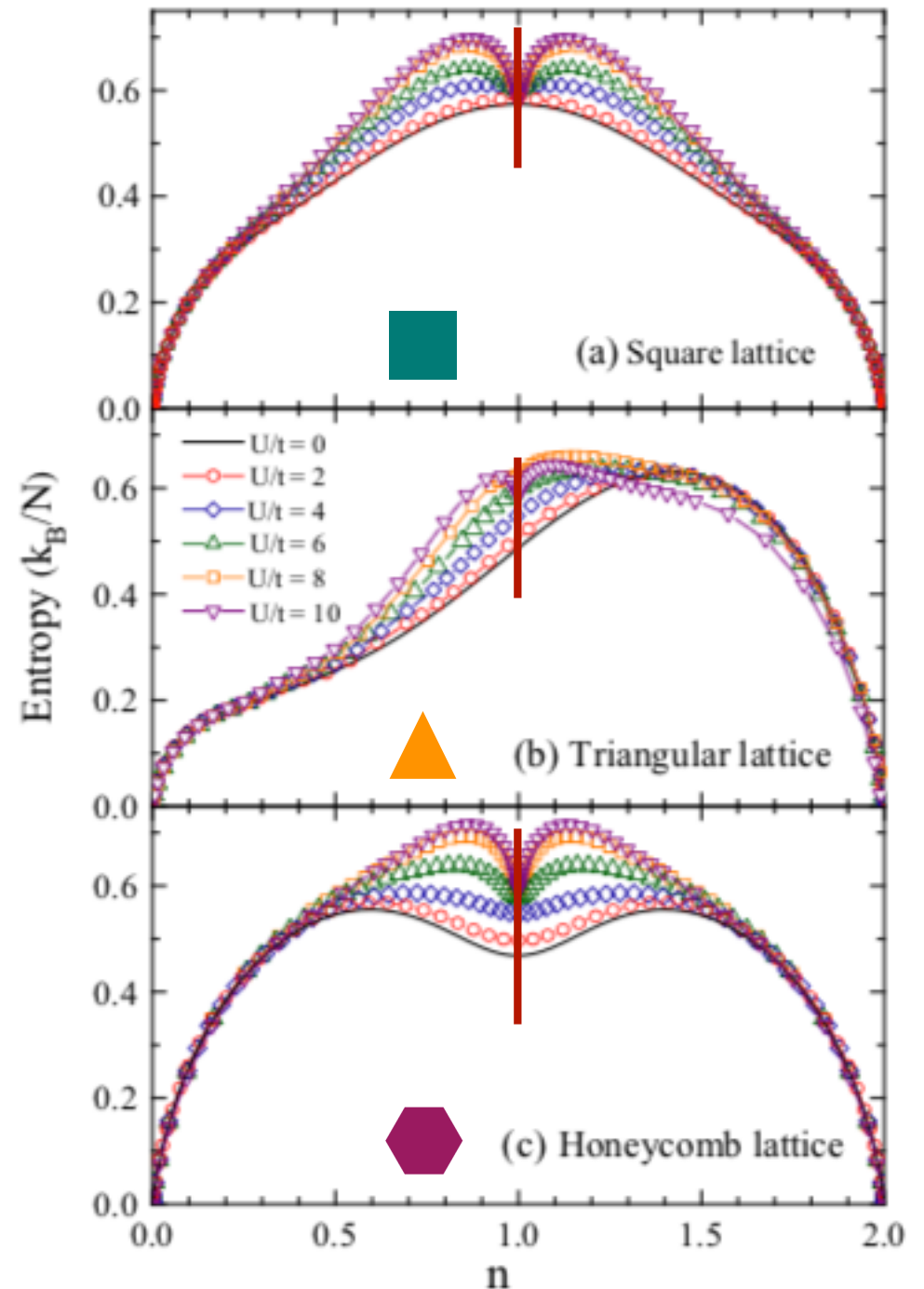


# Entropy

$$s(\mu, T) = \int_{-\infty}^{\mu} d\mu \left. \frac{\partial n}{\partial T} \right|_{\mu}$$

Correlations only play a role in a geometry dependent region around half-filling

Mott insulator has lower entropy than surrounding metal



## Density of States

$$G(\mathbf{r} = 0, \tau) = \int_{-\infty}^{\infty} d\omega \frac{e^{-\omega\tau}}{1 + e^{-\beta\omega}} N(\omega)$$

## Conductivity

$$\Lambda(\mathbf{q} = 0, \tau) = \int_{-\infty}^{\infty} \frac{d\omega}{\pi} \frac{e^{-\omega\tau}}{1 - e^{-\beta\omega}} \text{Im } \Lambda(\mathbf{q} = 0, \omega)$$

Key quantities obtained without inverting  
Laplace transforms

$$N(\omega = 0, T) = \frac{dn}{d\mu} = n^2 \kappa(T)$$

$$\sigma_{dc} \approx \frac{\beta^2}{\pi} \Lambda_{xx}(\mathbf{q} = \mathbf{0}, \tau = \beta/2)$$

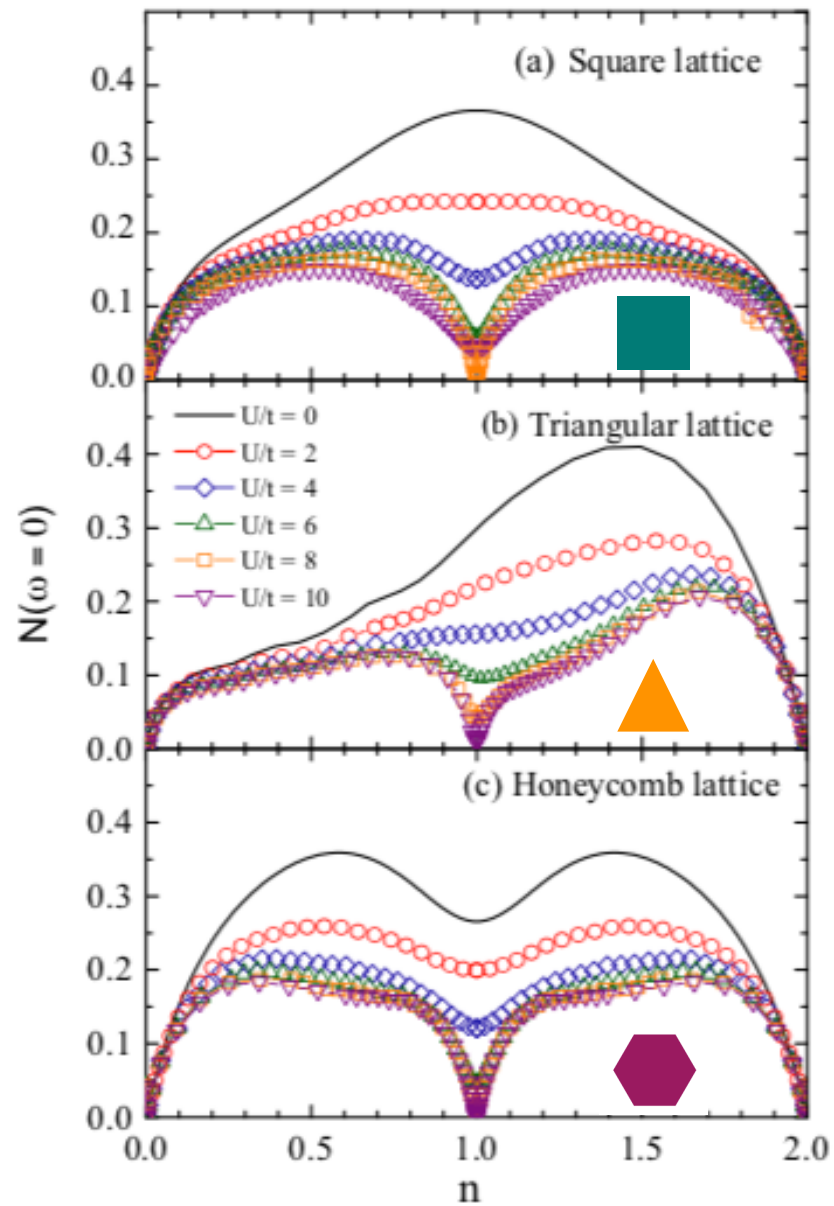
Current-current correlation function

$$\Lambda_{xx}(\mathbf{q}, \tau) = \langle j_x(\mathbf{q}, \tau) j_x(-\mathbf{q}, 0) \rangle$$

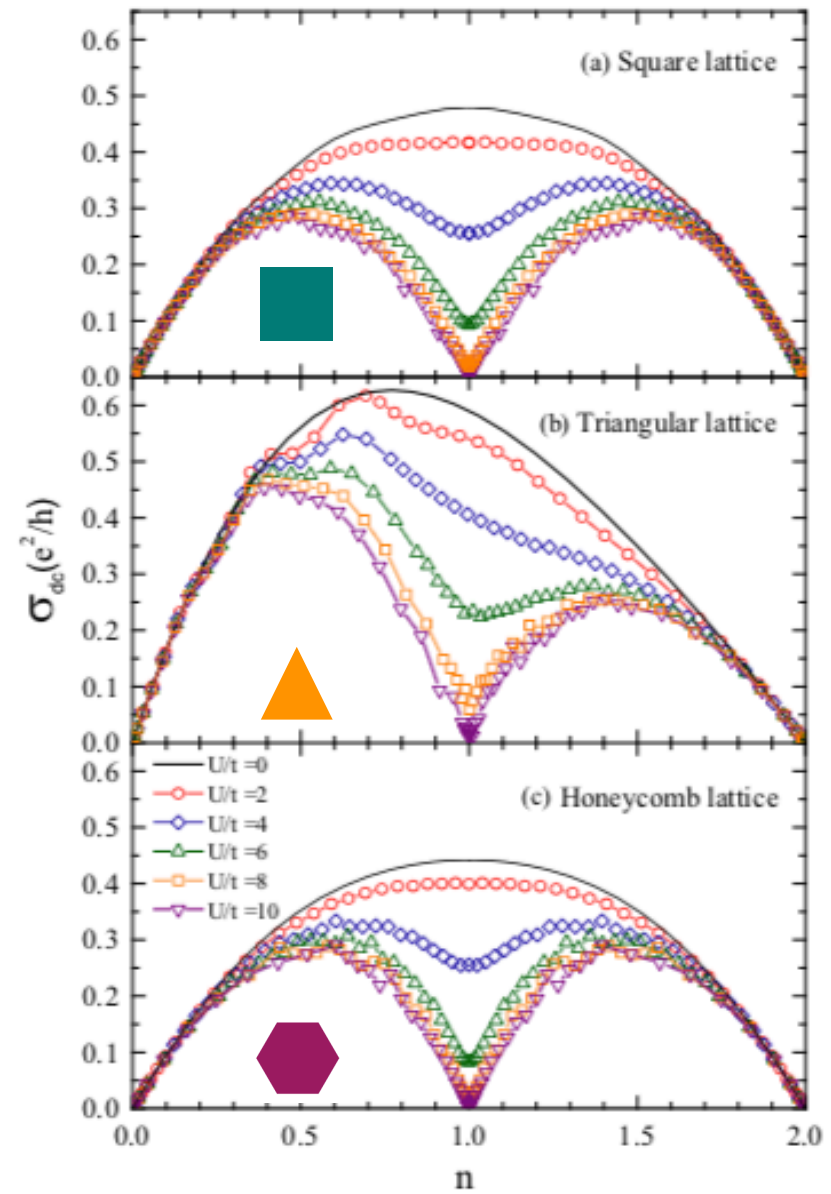
Unequal time current operator

$$j_x(\mathbf{i}, \tau) = e^{\tau\mathcal{H}} \left[ it \sum_{\sigma} \left( c_{\mathbf{i}+\mathbf{x},\sigma}^{\dagger} c_{\mathbf{i},\sigma} - c_{\mathbf{i},\sigma}^{\dagger} c_{\mathbf{i}+\mathbf{x},\sigma} \right) \right] e^{-\tau\mathcal{H}}$$

# Density of States



# Conductivity



# Seebeck coefficient

Kelvin formula

$$S_{Kelvin} = - \frac{1}{e} \frac{\partial \mu}{\partial T} \Big|_{V,n} = \frac{\partial s}{\partial n} \Big|_{T,V}$$

Low frequency:  $\hbar\omega < U$

Sign is related to carrier:

negative for holes  $+$  and

positive for electrons  $-$

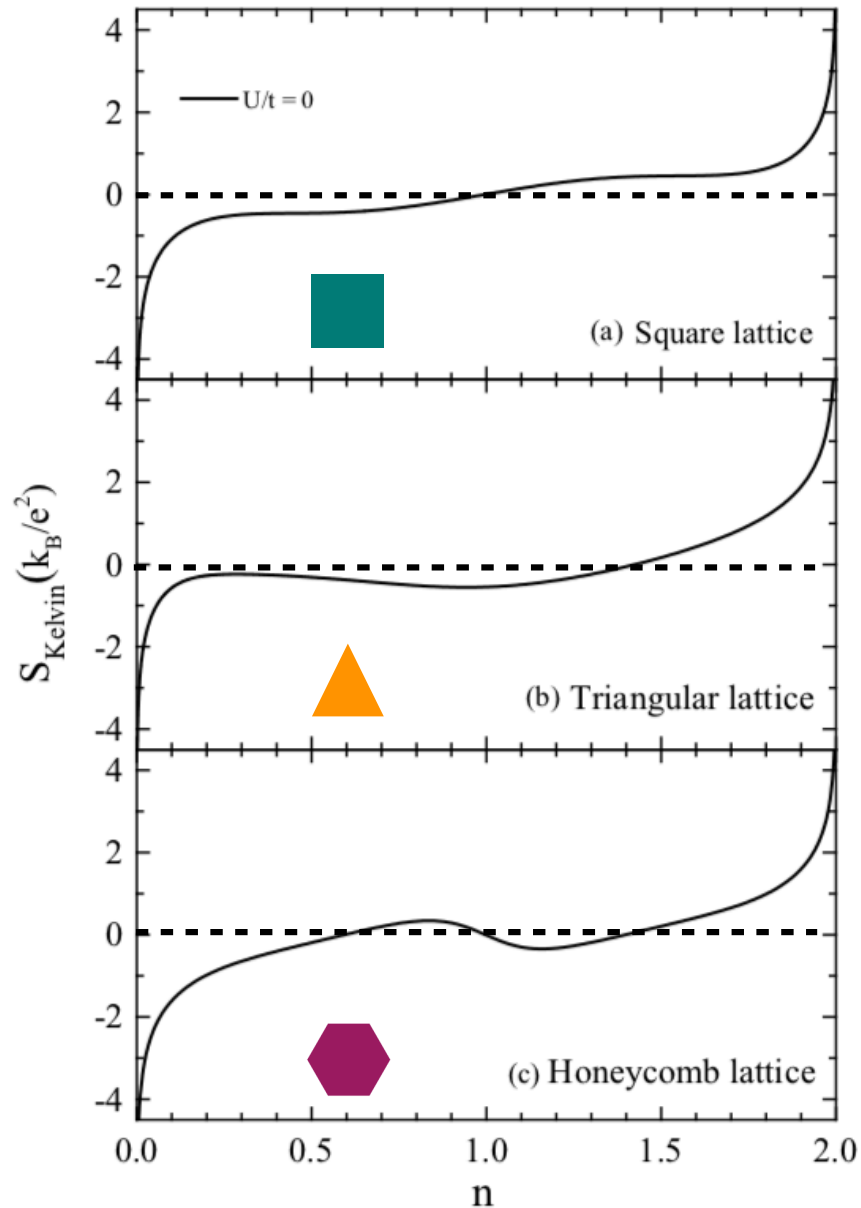
# Seebeck coefficient

Non-interacting case

Geometry effects

$T/t=0.5$

Change of sign: change of carrier



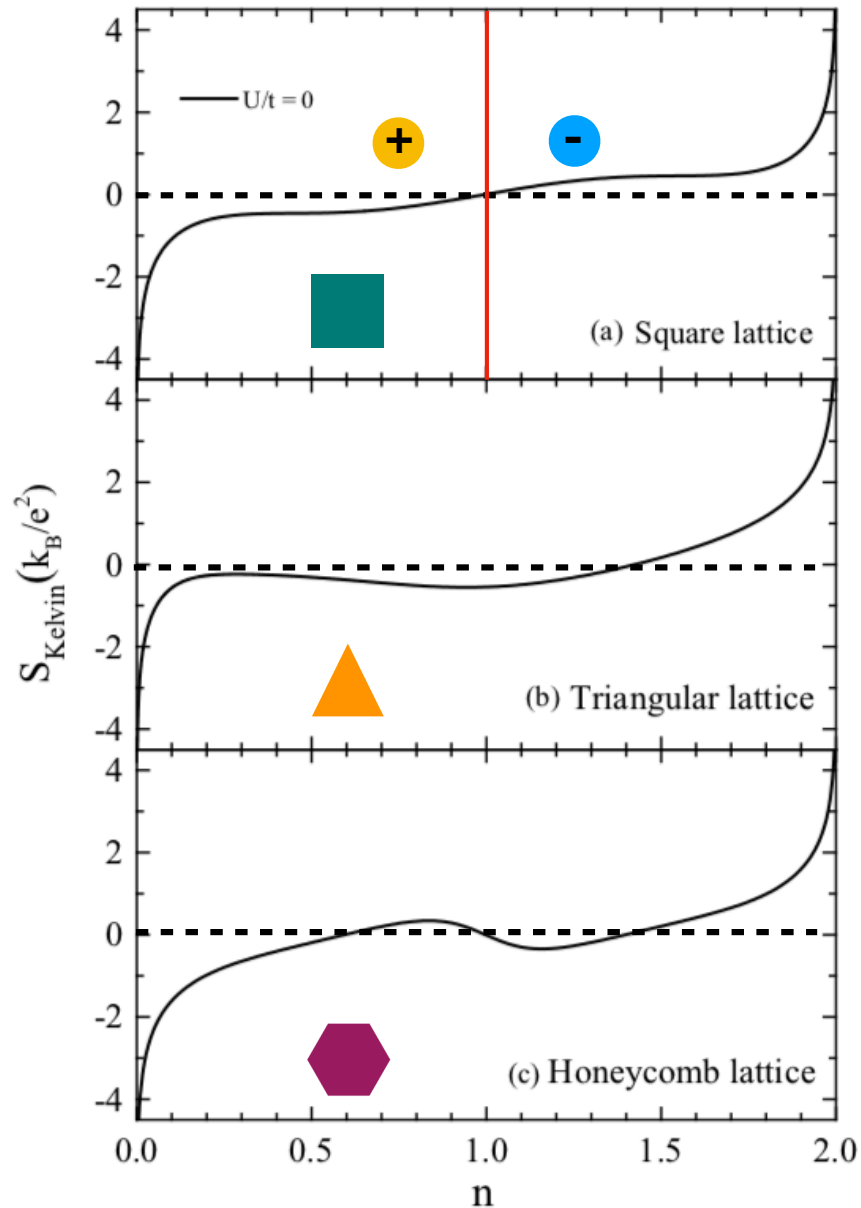
# Seebeck coefficient

Non-interacting case

Geometry effects

$T/t=0.5$

Change of sign: change of carrier



■ → Half-filling

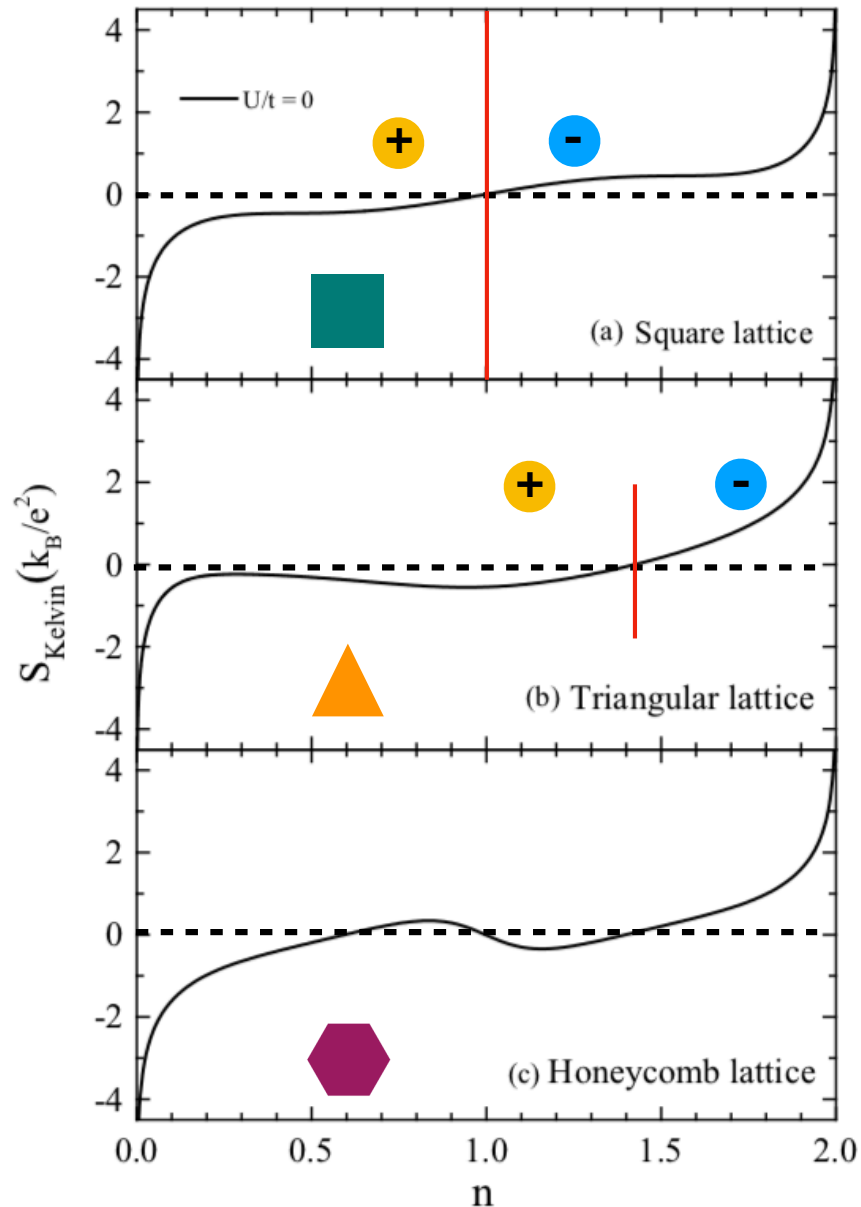
# Seebeck coefficient

Non-interacting case

Geometry effects

$T/t=0.5$

Change of sign: change of carrier



■ → Half-filling

▲ →  $n=1.42$

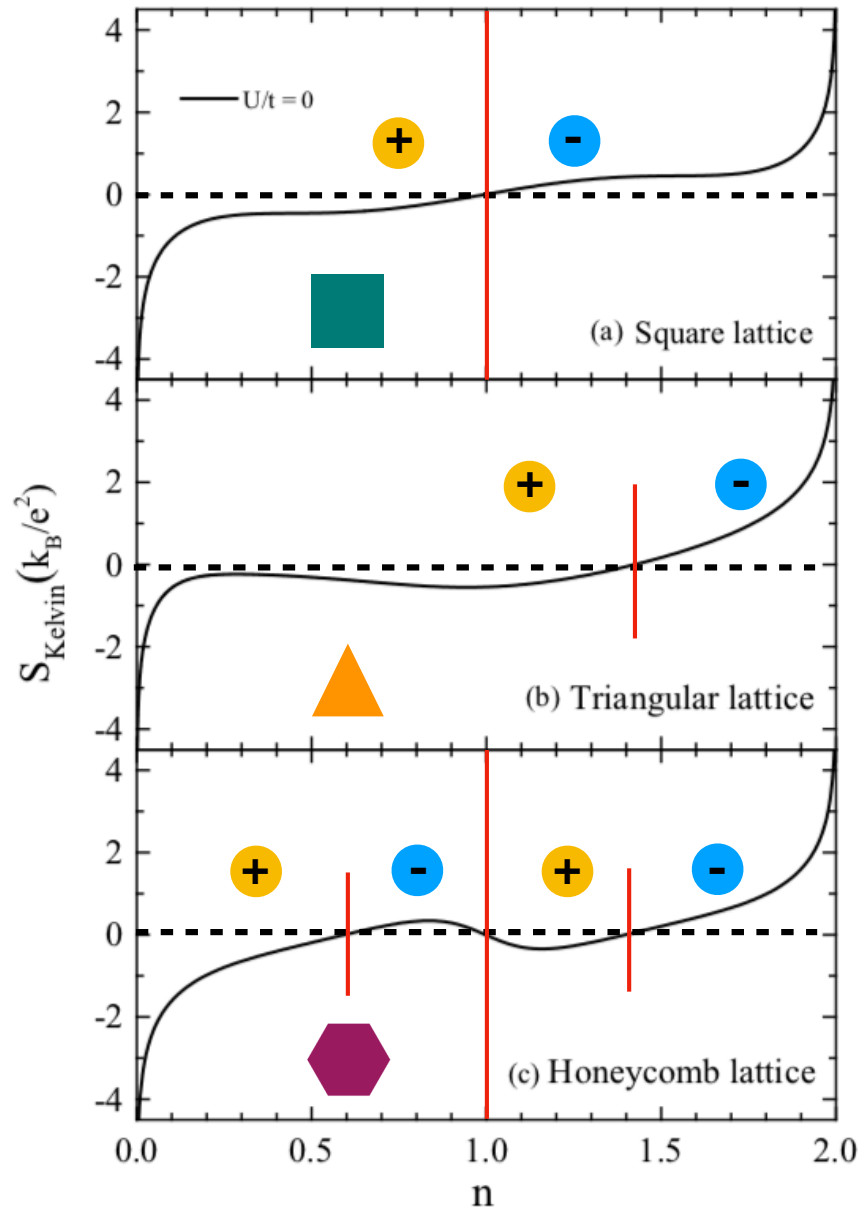
# Seebeck coefficient




Non-interacting case

Geometry effects

$T/t=0.5$

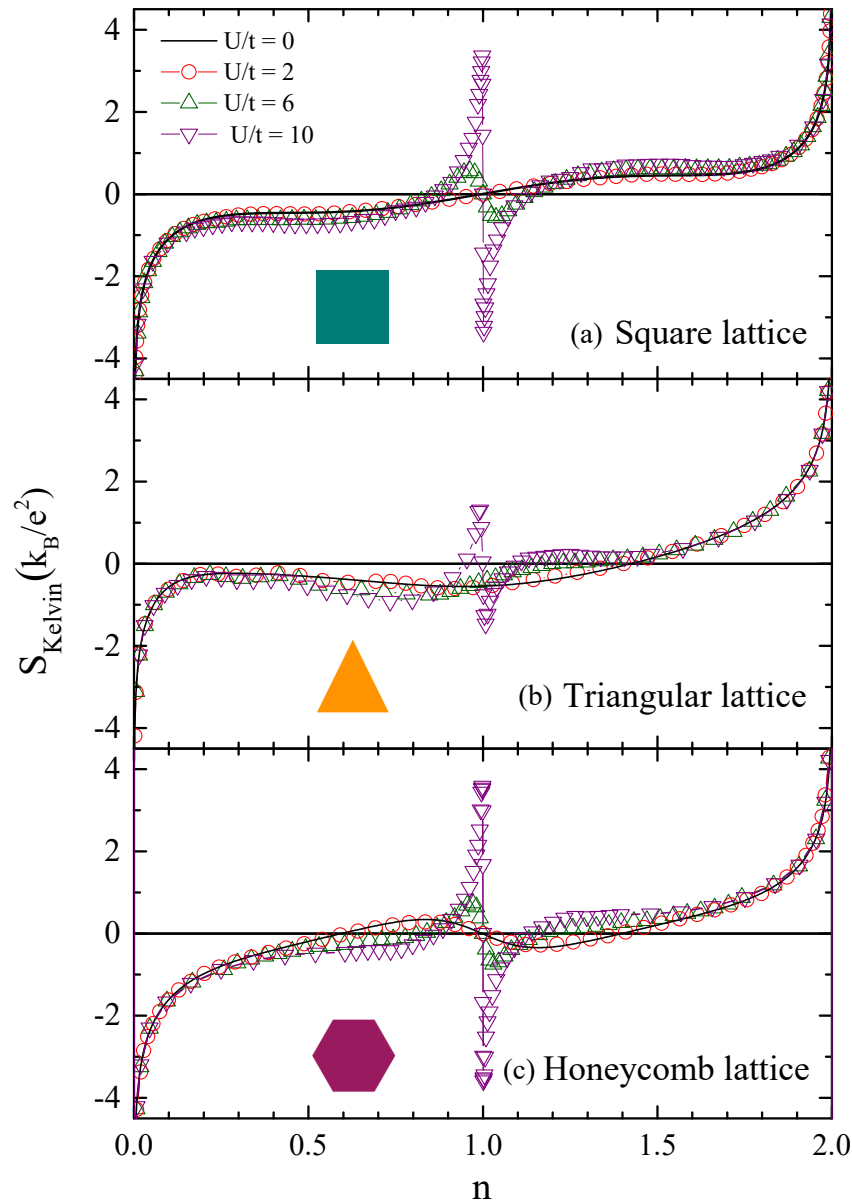
Change of sign: change of carrier



-   $\rightarrow$  Half-filling
-   $\rightarrow$   $n=1.42$
-   $\rightarrow$   $n=0.6, 1.0$  and  $1.4$



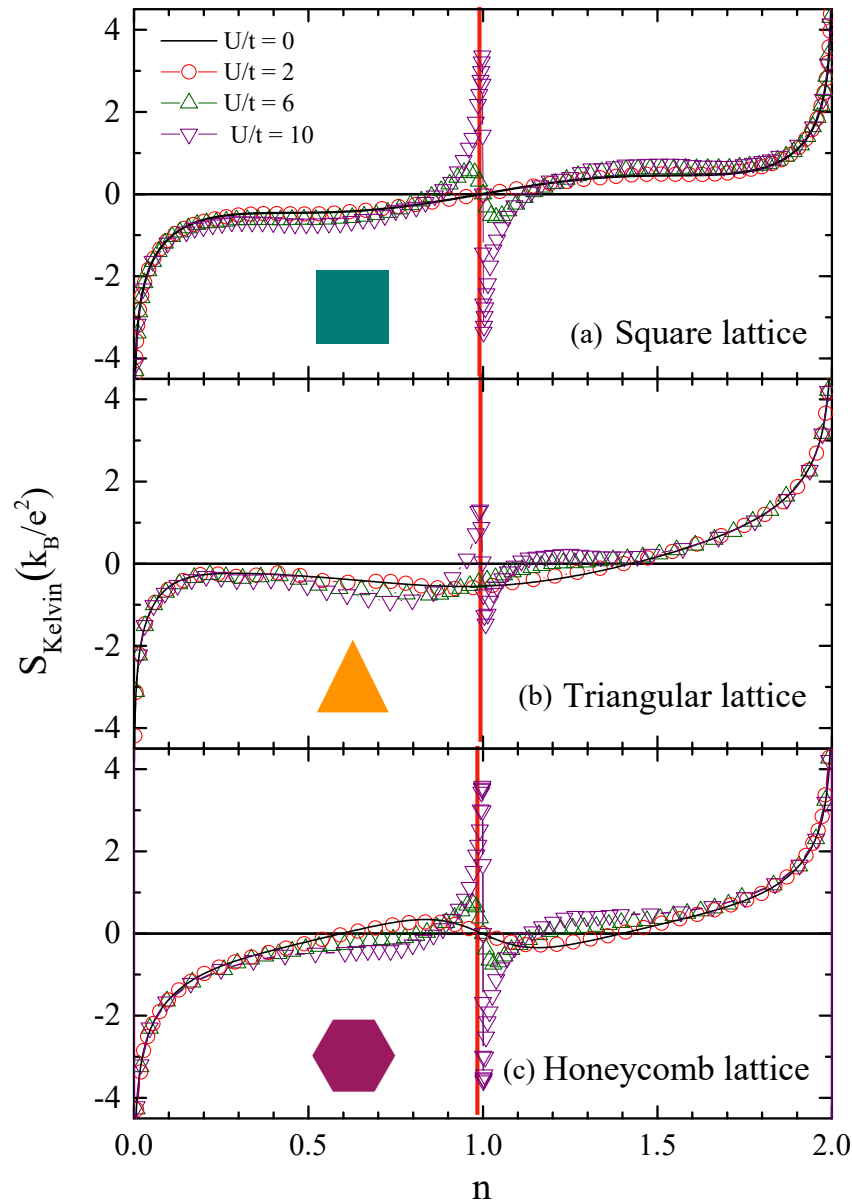
# Seebeck coefficient



Role of Interactions

Strong increase near half-filling

# Seebeck coefficient

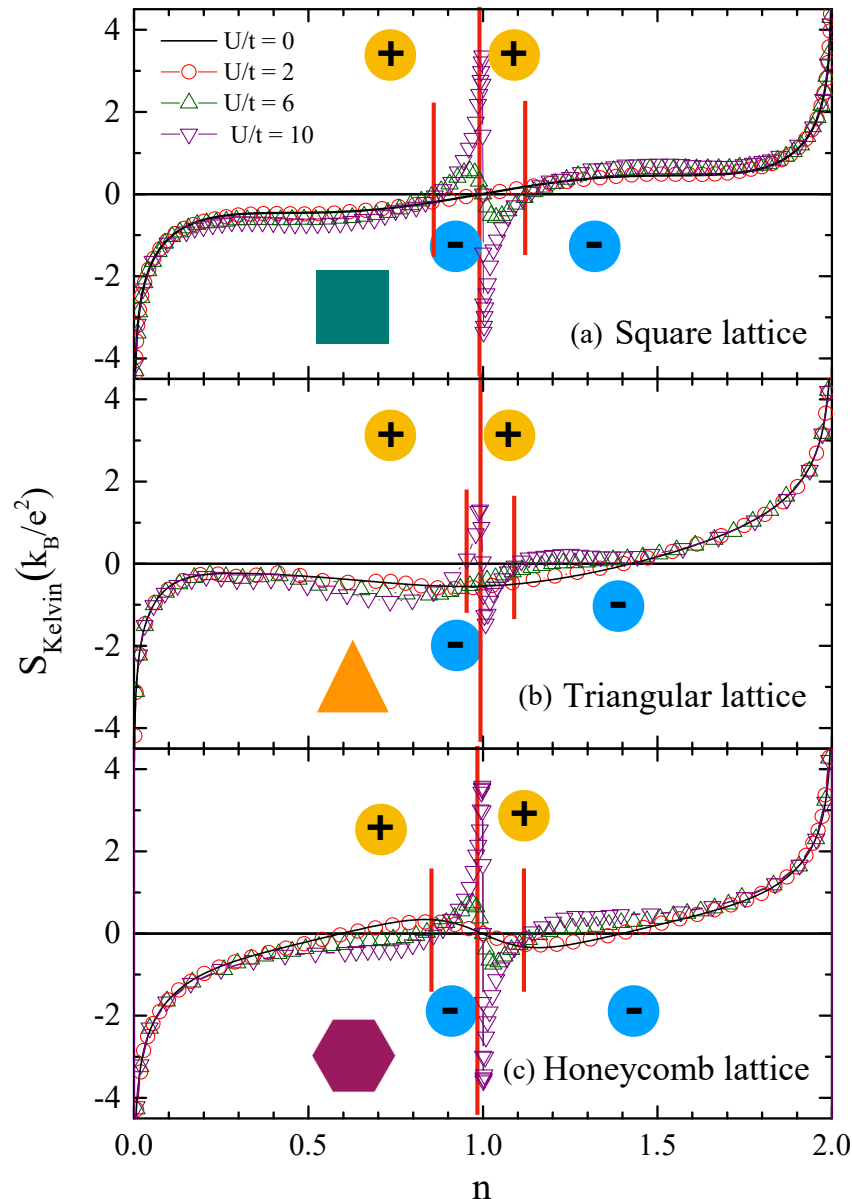


Role of Interactions

Strong increase near half-filling

Triangular lattice at half-filling:  
change of sign  $\rightarrow$  Mott  
transition

# Seebeck coefficient



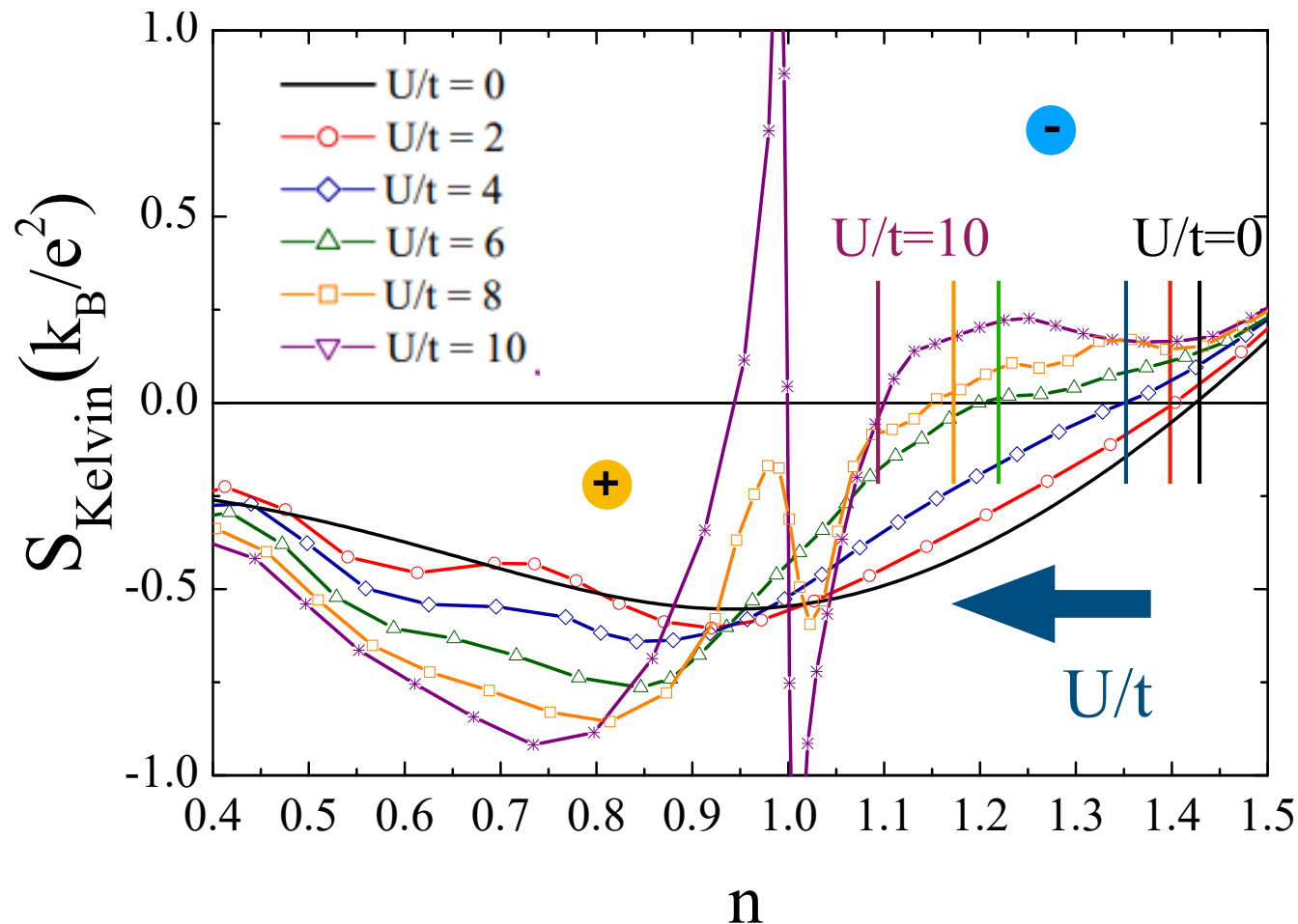
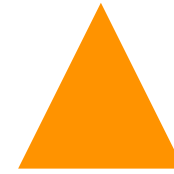
Role of Interactions

Strong increase near half-filling

Triangular lattice at half-filling: change of sign  $\rightarrow$  Mott transition

Additional sign changing densities

# Seebeck coefficient for the triangular lattice

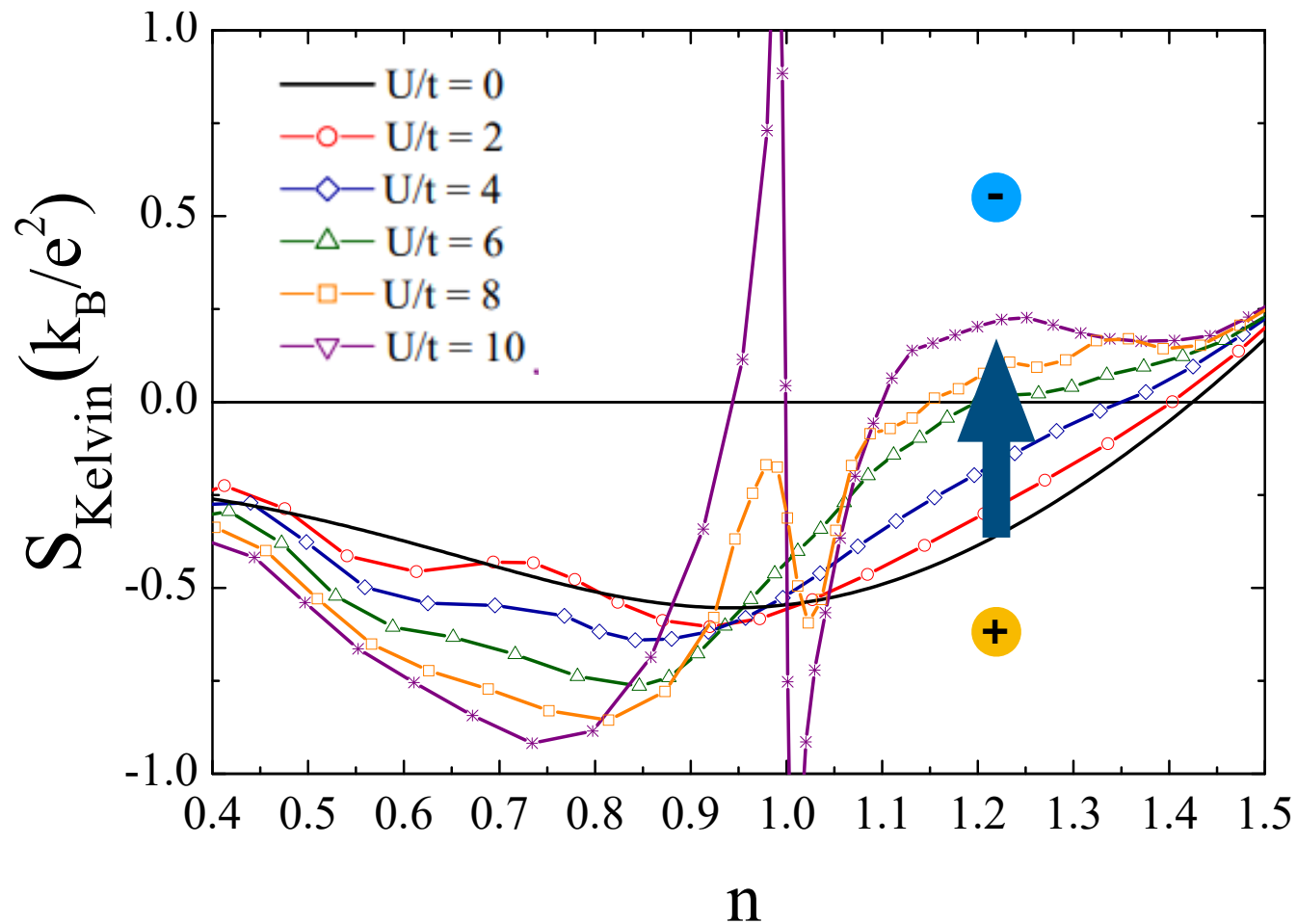
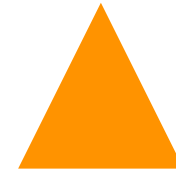


$U/t$  dependent  
number of crossings

Large  $U/t \rightarrow$  strong  
increase near half-  
filling

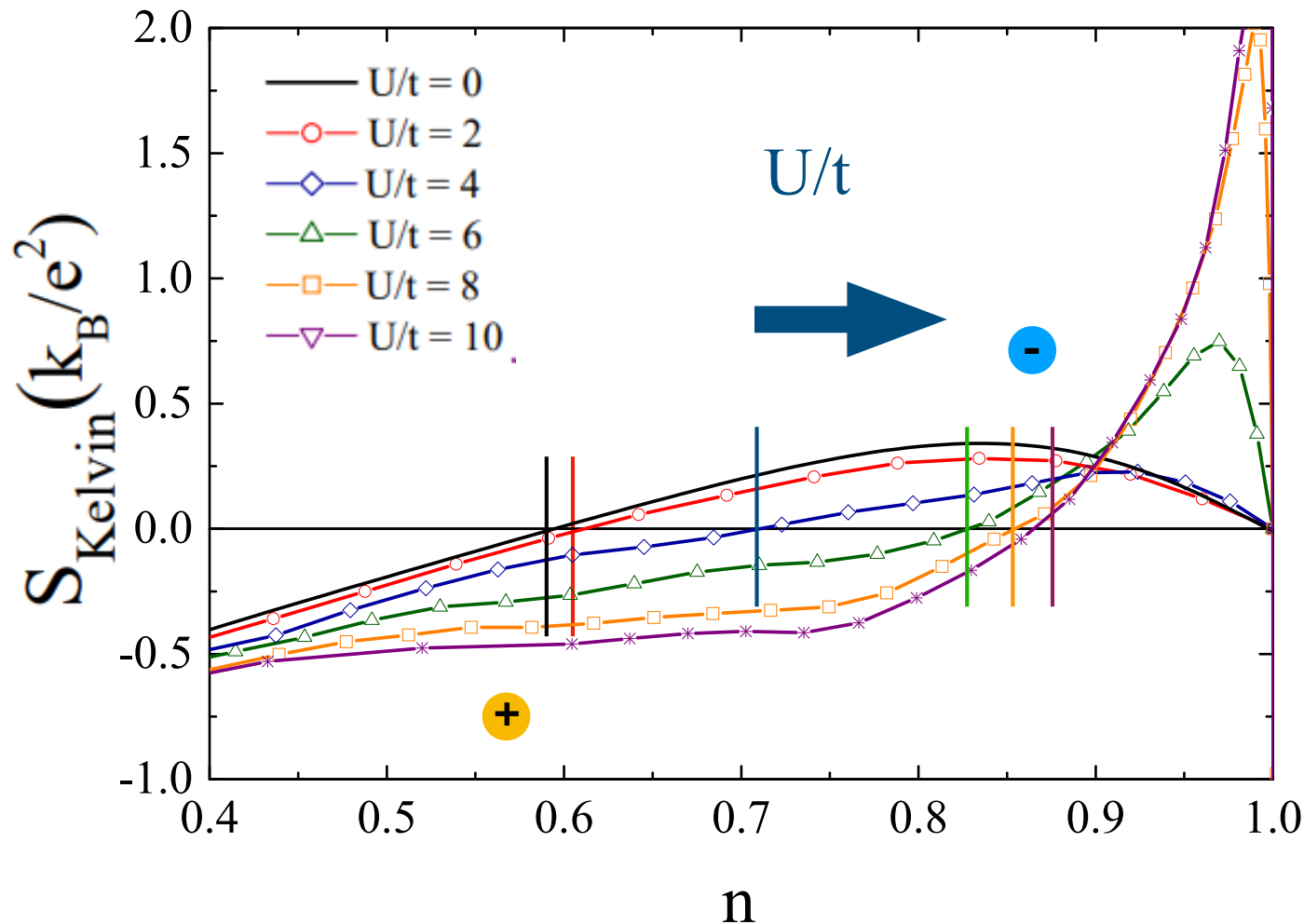
Sign changes move  
to lower densities as  
 $U/t$  increases

# Seebeck coefficient for the triangular lattice



Increasing  $U/t$   
changes carriers from  
holes to electrons

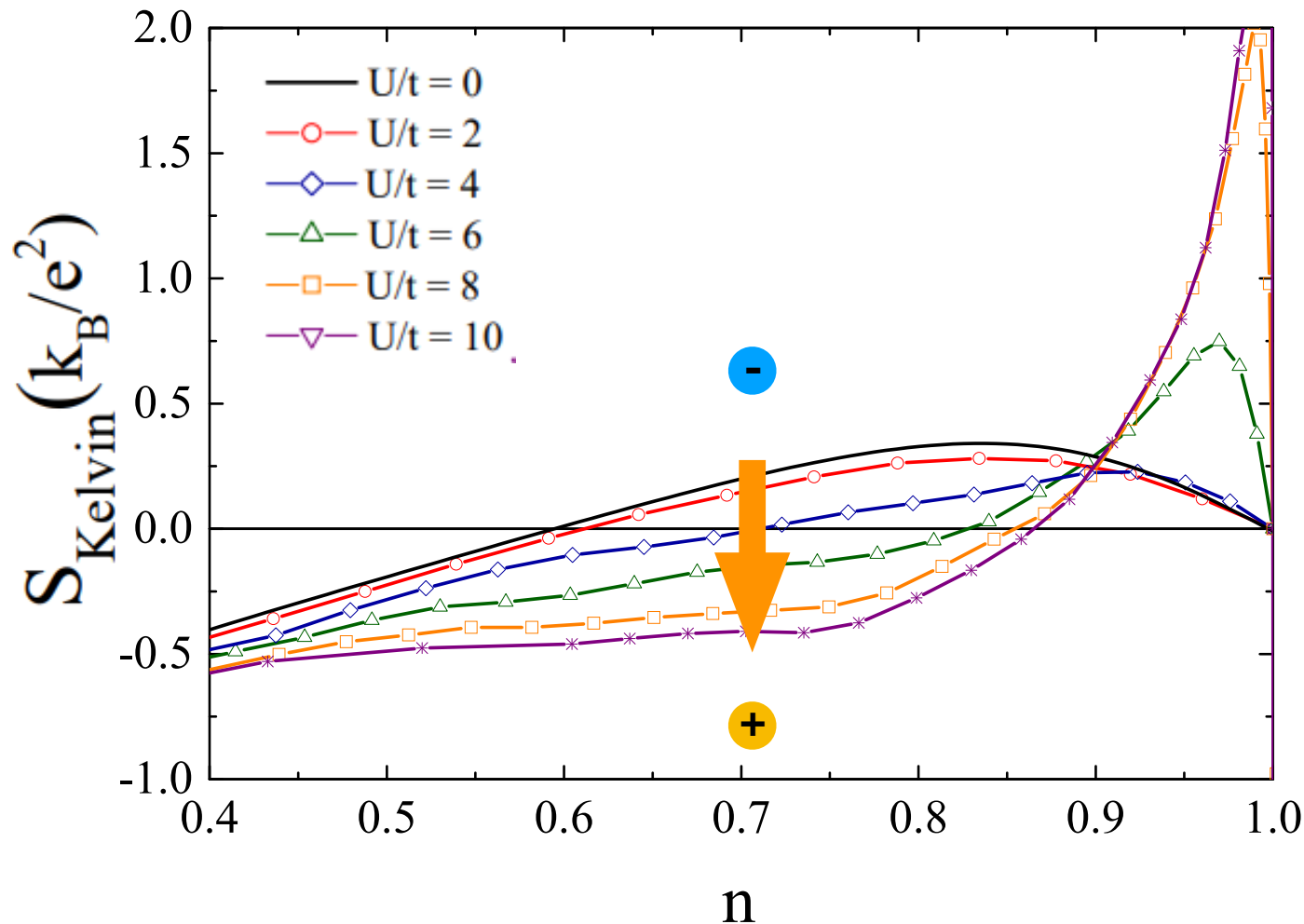
# Seebeck coefficient for the Honeycomb lattice



Large  $U/t \rightarrow$  Strong increase near half-filling

Sign changes move to higher (lower) densities below (above) half-filling as  $U/t$  increases

# Seebeck coefficient for the Honeycomb lattice

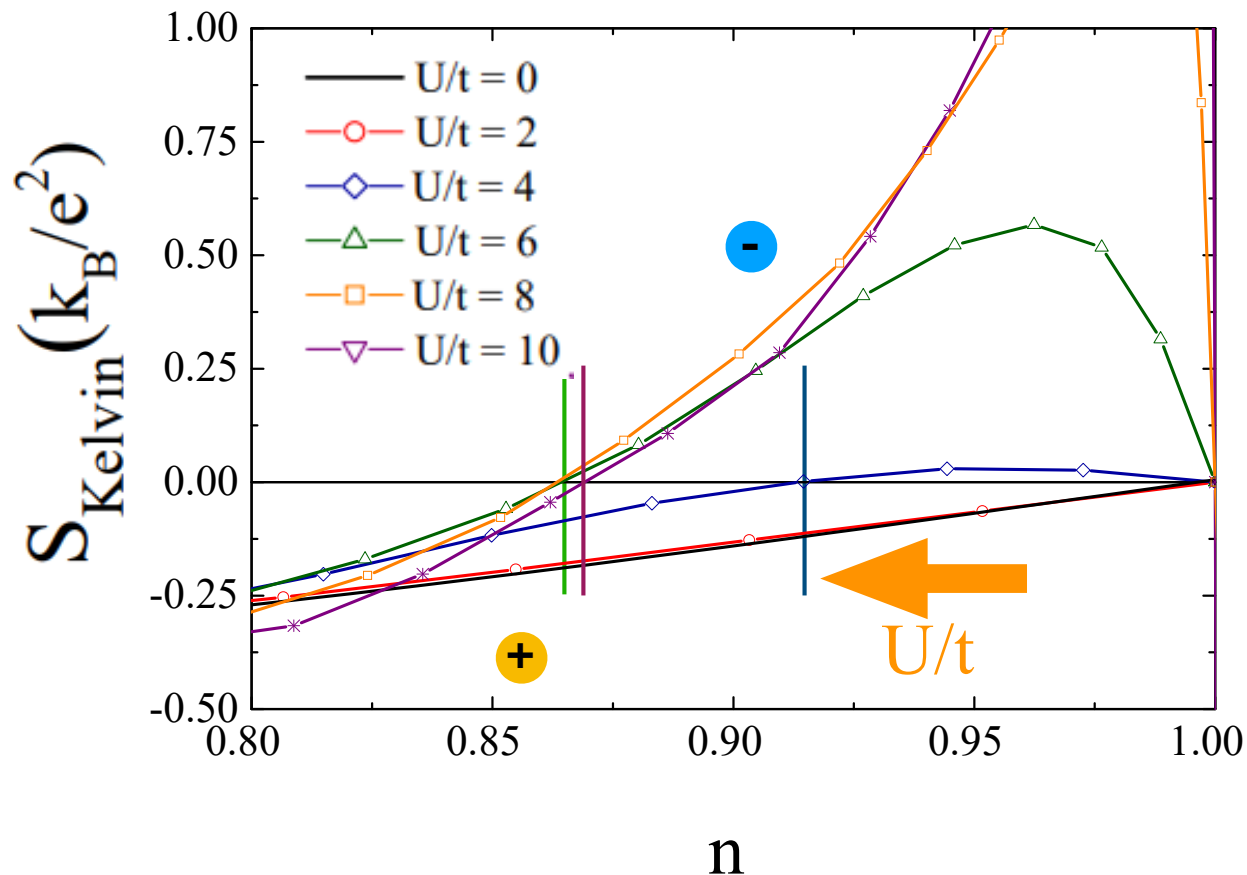


Increasing  $U/t$   
changes carriers from  
electrons to holes for  
 $0.6 < n < 0.85$

$P$ - $h$  symmetry

Increasing  $U/t$   
changes carriers from  
holes to electrons for  
 $1.2 < n < 1.7$ .

# Seebeck coefficient for square lattice



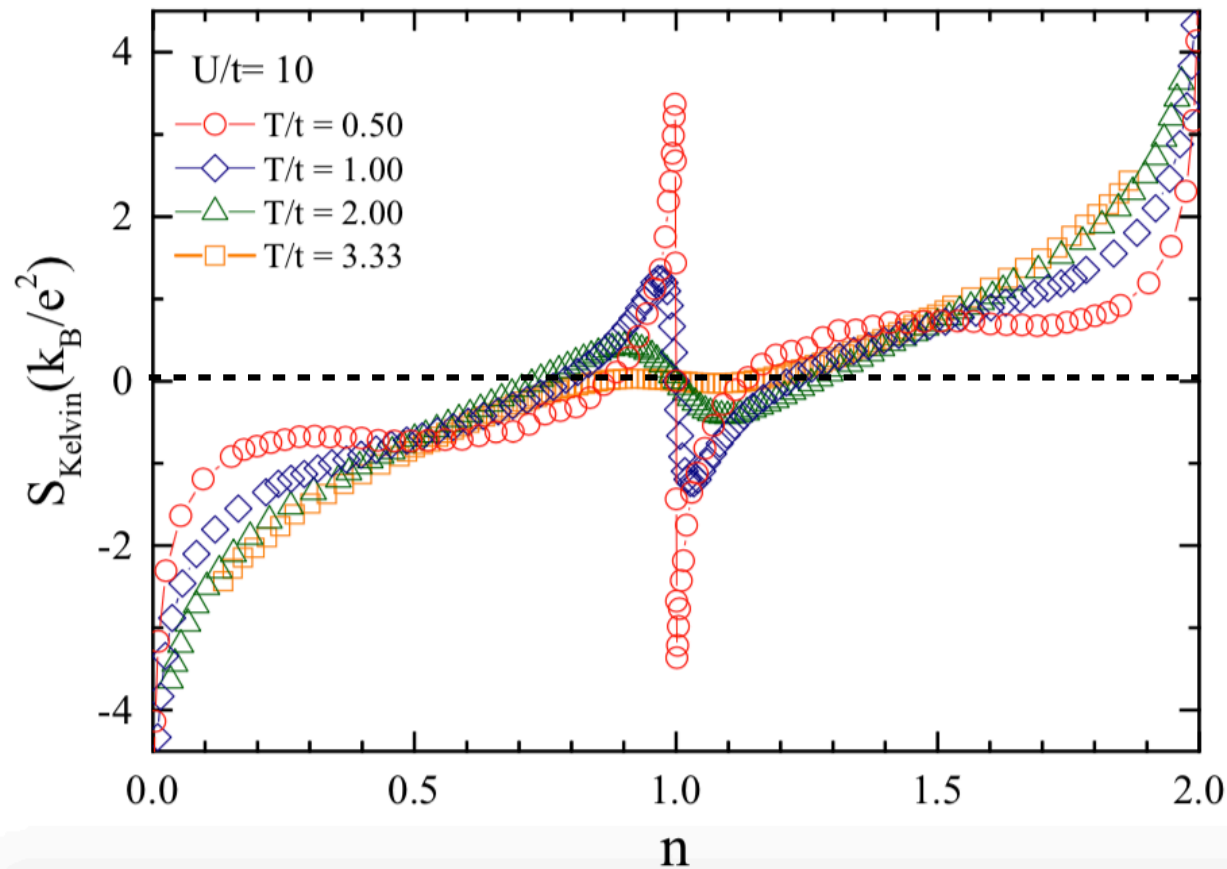
Large  $U/t \rightarrow$  Strong increase near half-filling

Sign changes move to lower (higher) densities below (above) half-filling as  $U/t$  increases

Change of sign pushed to smaller  $U/t$

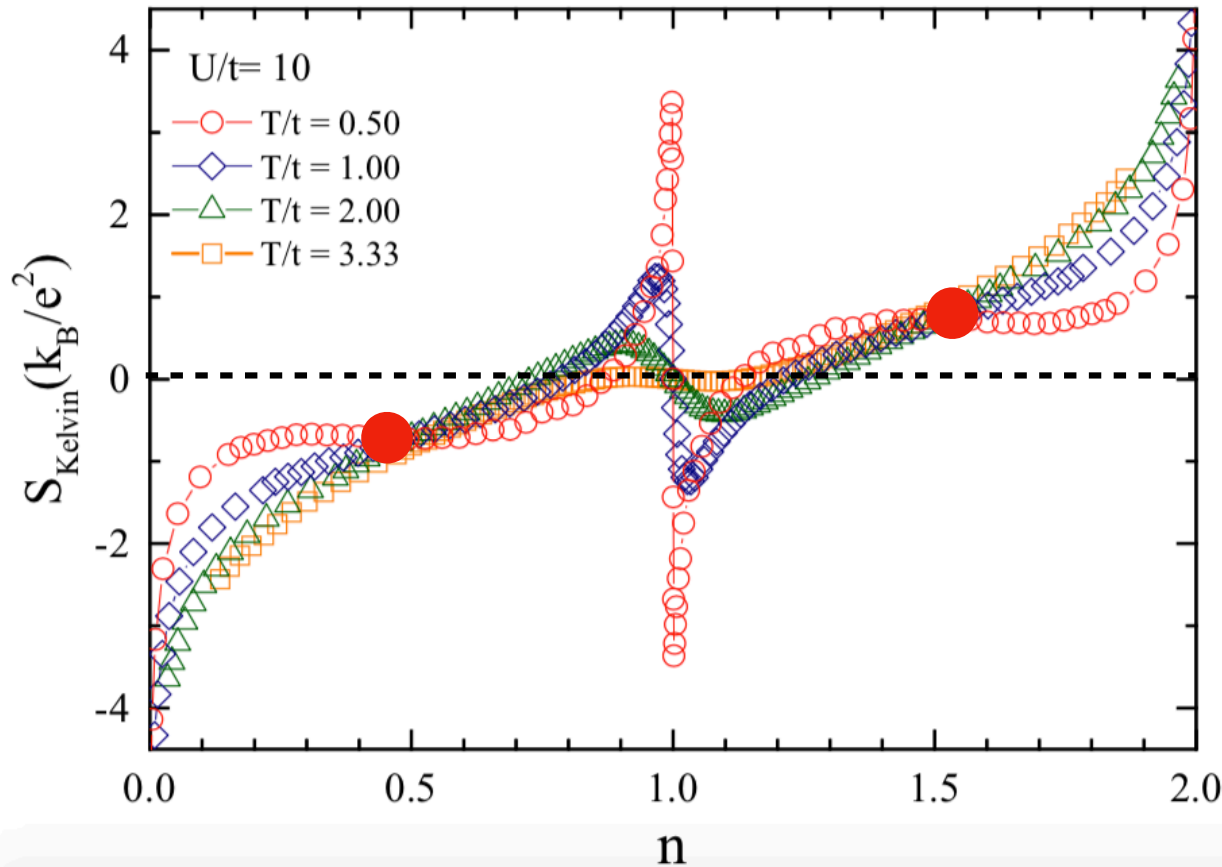


# Effect of temperature for the square lattice



Decreasing temperature increases Seebeck effect near half-filling

# Effect of temperature for the square lattice

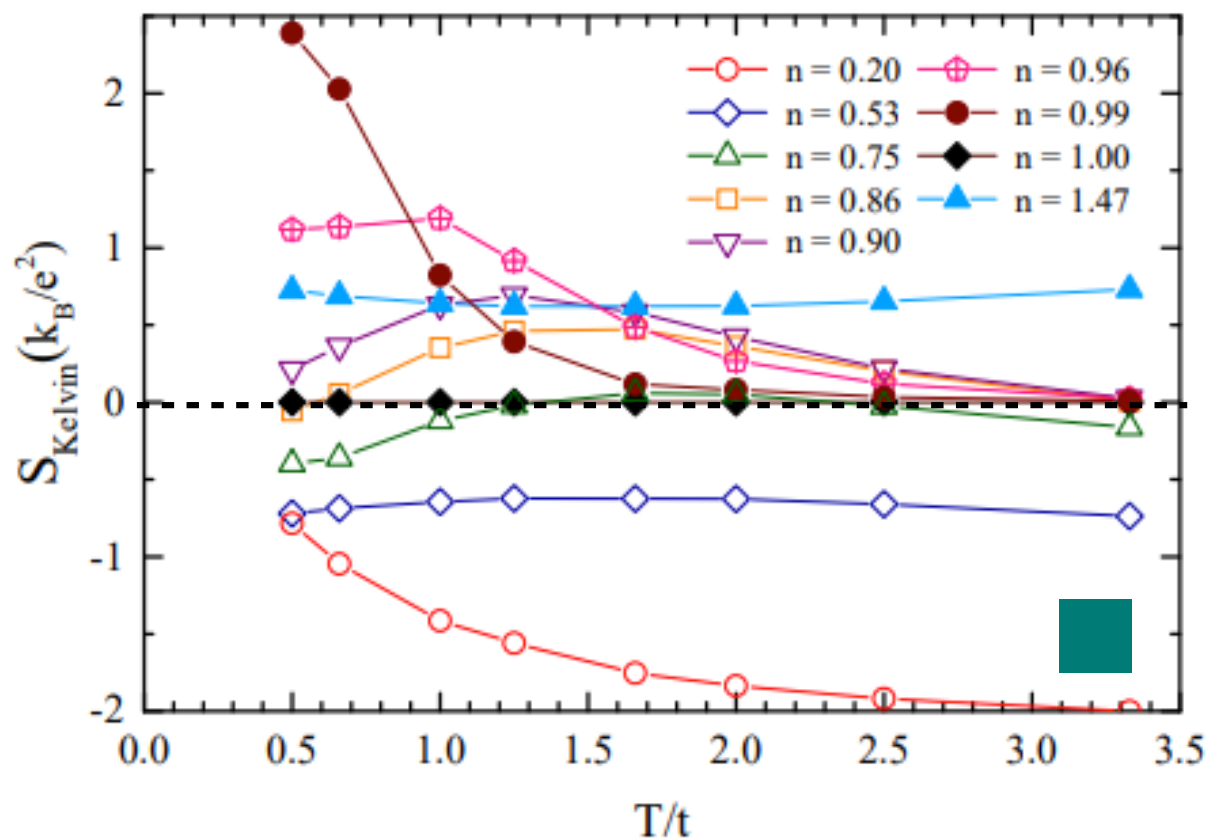


Decreasing temperature increases Seebeck effect near half-filling

Temperature independent densities  $n = 0.5$  and  $1.5$

Isosbestic points

# Effect of temperature for the square lattice



$n = 1.47$



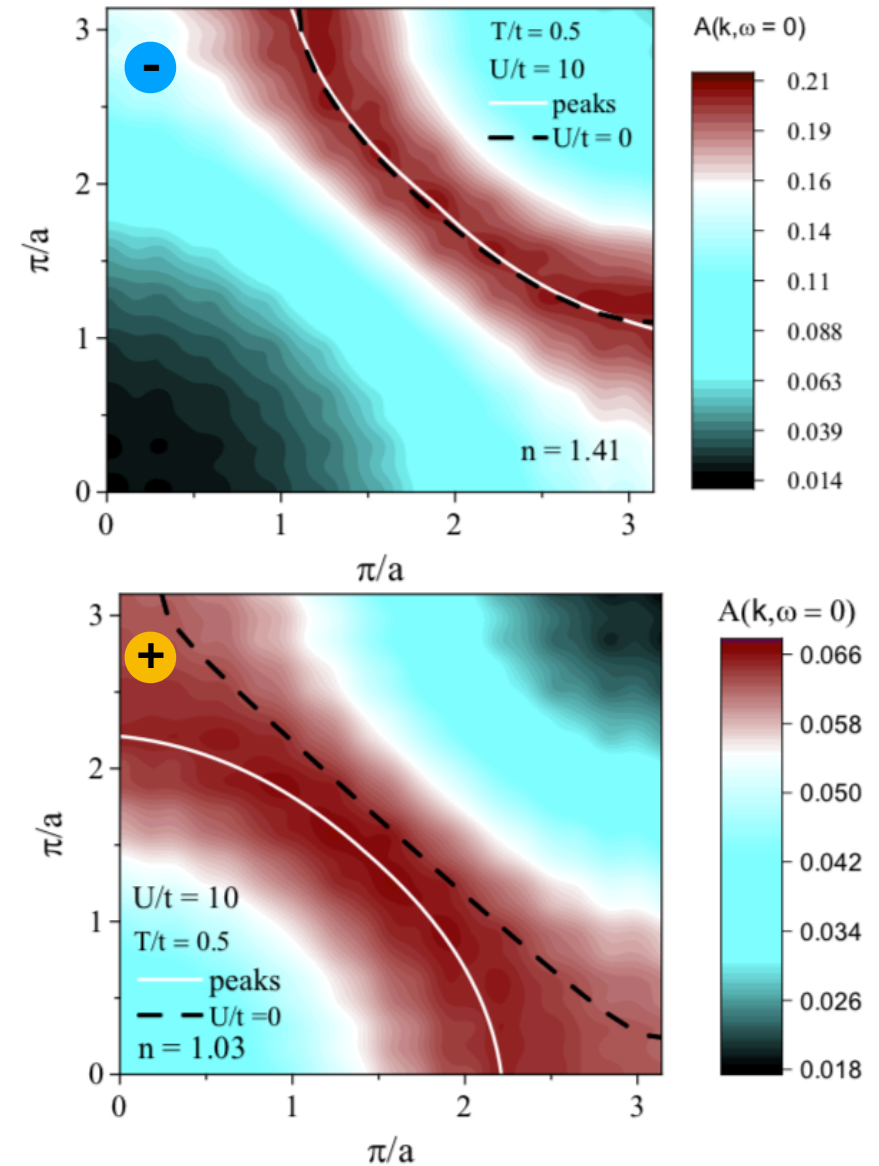
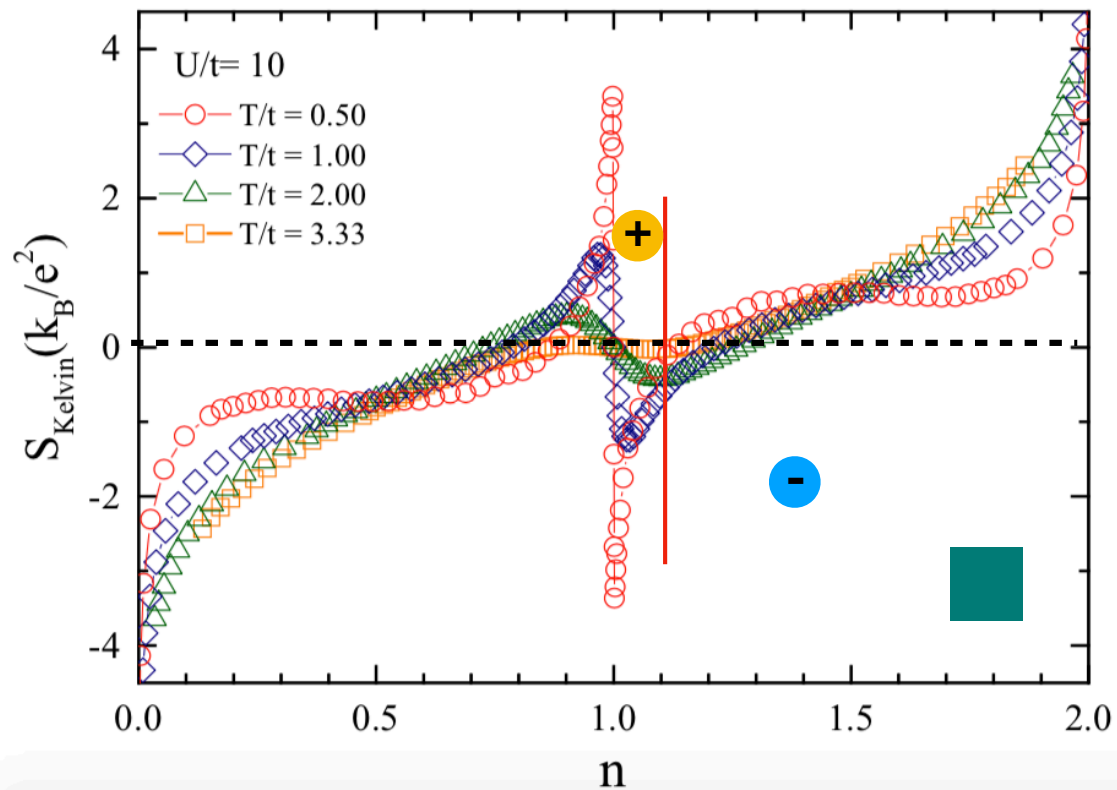
$n = 1.0$



$n = 0.53$



# Fermi surface reconstruction



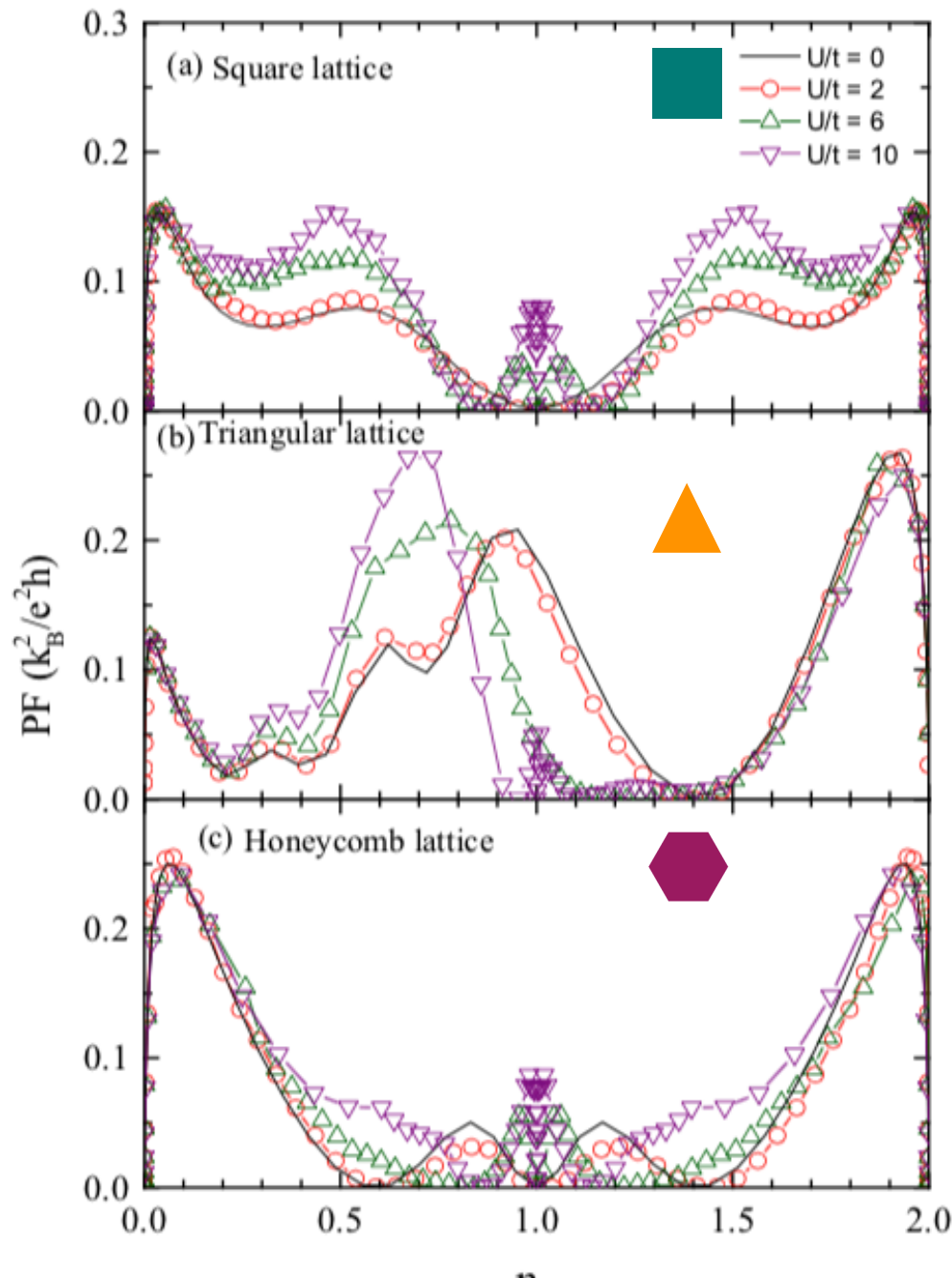
# Power factor

$$PF = S^2 \sigma$$

Increased by correlations in the vicinity of half-filling

can be tuned by interactions

At intermediate densities (around  $n = 0.4 - 0.6$  and  $n = 1.4 - 1.6$ ) the peaks in PF have a strong contribution from the conductivity with positions strongly dependent on geometry.



# Conclusions

Anomalous Seebeck effect near half-filling: change in sign signals the Fermi surface reconstruction

Anomaly intensified by temperature reduction and increased correlations

Away from half-filling, at intermediate densities (around  $n = 0.4 - 0.6$  and  $n = 1.4 - 1.6$ ) the peaks in PF have a strong contribution from the conductivity with positions strongly dependent on geometry.

The thermoelectric Power Factor displays a competition between the Seebeck coefficient and the conductivity



# Thank you!



Photograph by Ignazio Sciacca

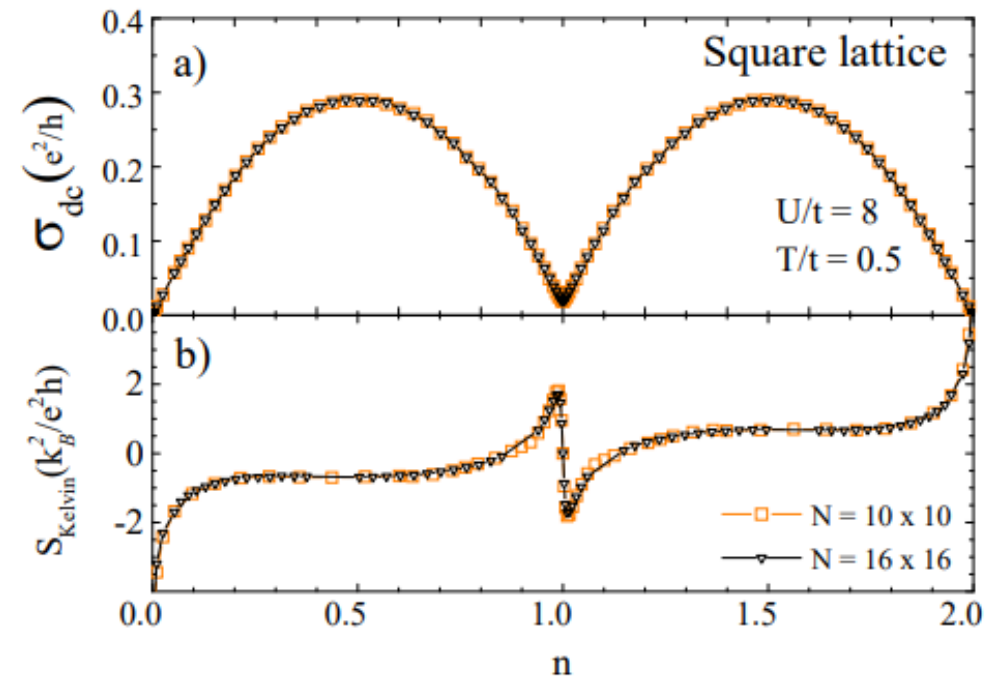
NATIONAL GEOGRAPHIC TRAVELER PHOTO CONTEST 2012  
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Feliz aniversário, Eduardo!





## Size effects



$T/t=0.5$

Irrelevant at this temperature

## Density of States

$$N(\omega = 0) \approx \frac{\beta}{\pi} G(|\mathbf{i} - \mathbf{j}| = \mathbf{0}, \tau = \beta/2)$$

$$\tau = \beta/2$$

$$\beta = 1/k_B T$$

## Conductivity

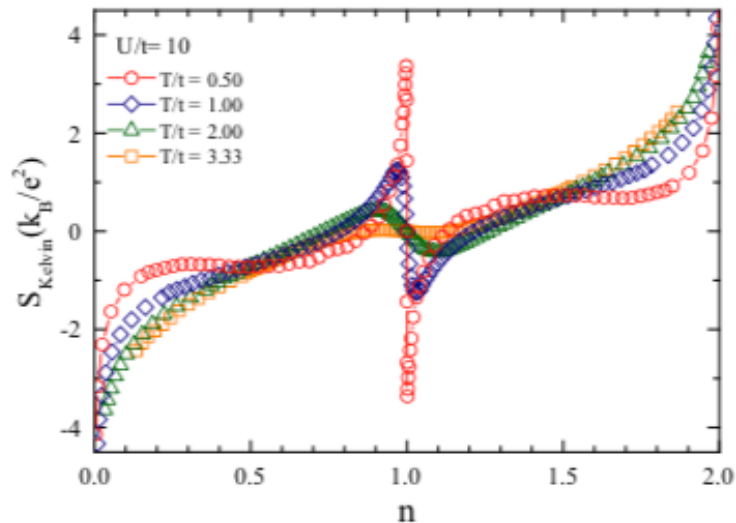
$$\sigma_{dc} \approx \frac{\beta^2}{\pi} \Lambda_{xx}(\mathbf{q} = \mathbf{0}, \tau = \beta/2)$$

$$\Lambda_{xx}(\mathbf{q}, \tau) = \langle j_x(\mathbf{q}, \tau) j_x(-\mathbf{q}, 0) \rangle$$

$$j_x(\mathbf{i}, \tau) = e^{\tau \mathcal{H}} \left[ it \sum_{\sigma} \left( c_{\mathbf{i}+\mathbf{x},\sigma}^{\dagger} c_{\mathbf{i},\sigma} - c_{\mathbf{i},\sigma}^{\dagger} c_{\mathbf{i}+\mathbf{x},\sigma} \right) \right] e^{-\tau \mathcal{H}}$$

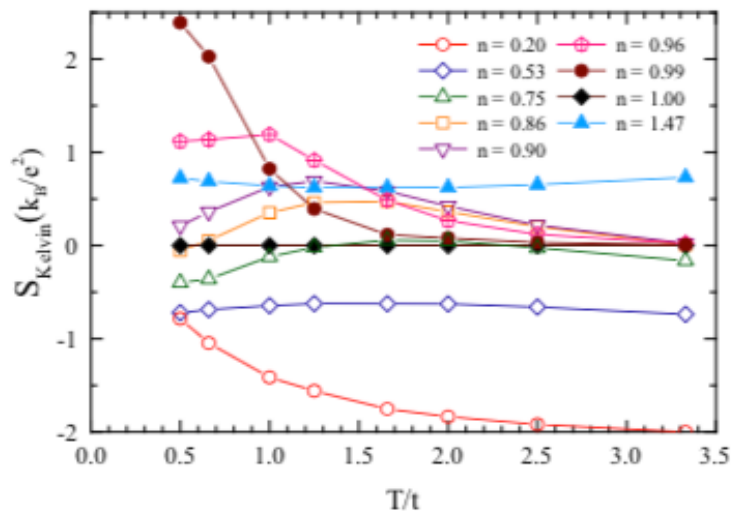
# Seebeck coefficient

Temperature effects



Square lattice

Decreasing temperature  
increases Seebeck effect near  
half-filling






Temperature independent  
densities  $n = 0.5$  and  $1.5$

# Power factor

Figure of merit

$$ZT = \frac{S^2 \sigma T}{\kappa}$$

$S$		Thermopower or Seebeck coefficient
$\sigma$		conductivity
$\kappa$		Thermal conductivity

$$PF = S^2 \sigma$$

Competition between Seebeck coefficient and conductivity

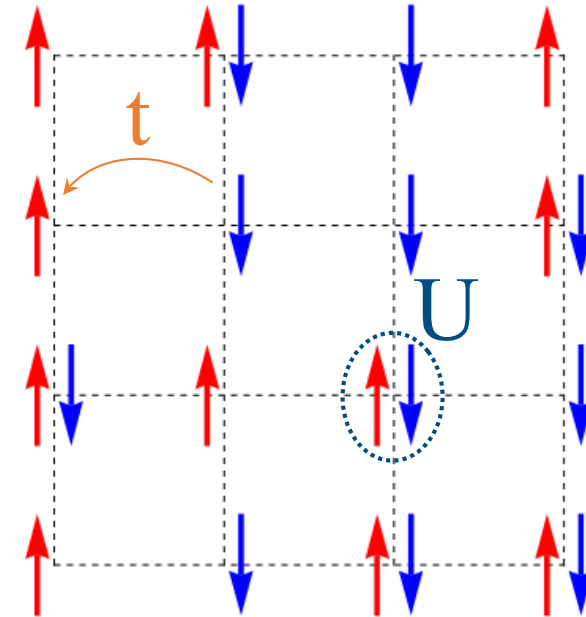
# Hubbard Model

$$\mathcal{H} = -\mathbf{t} \sum_{\langle i,j \rangle, \sigma} \left( \hat{c}_{i,\sigma}^\dagger \hat{c}_{j,\sigma} + h.c. \right) + \mathbf{U} \sum_i \left( \hat{n}_{i\uparrow} - \frac{1}{2} \right) \left( \hat{n}_{i\downarrow} - \frac{1}{2} \right) - \mu \hat{N}$$

Coulomb repulsion ( $U > 0$ )

Hopping ( $t$ )

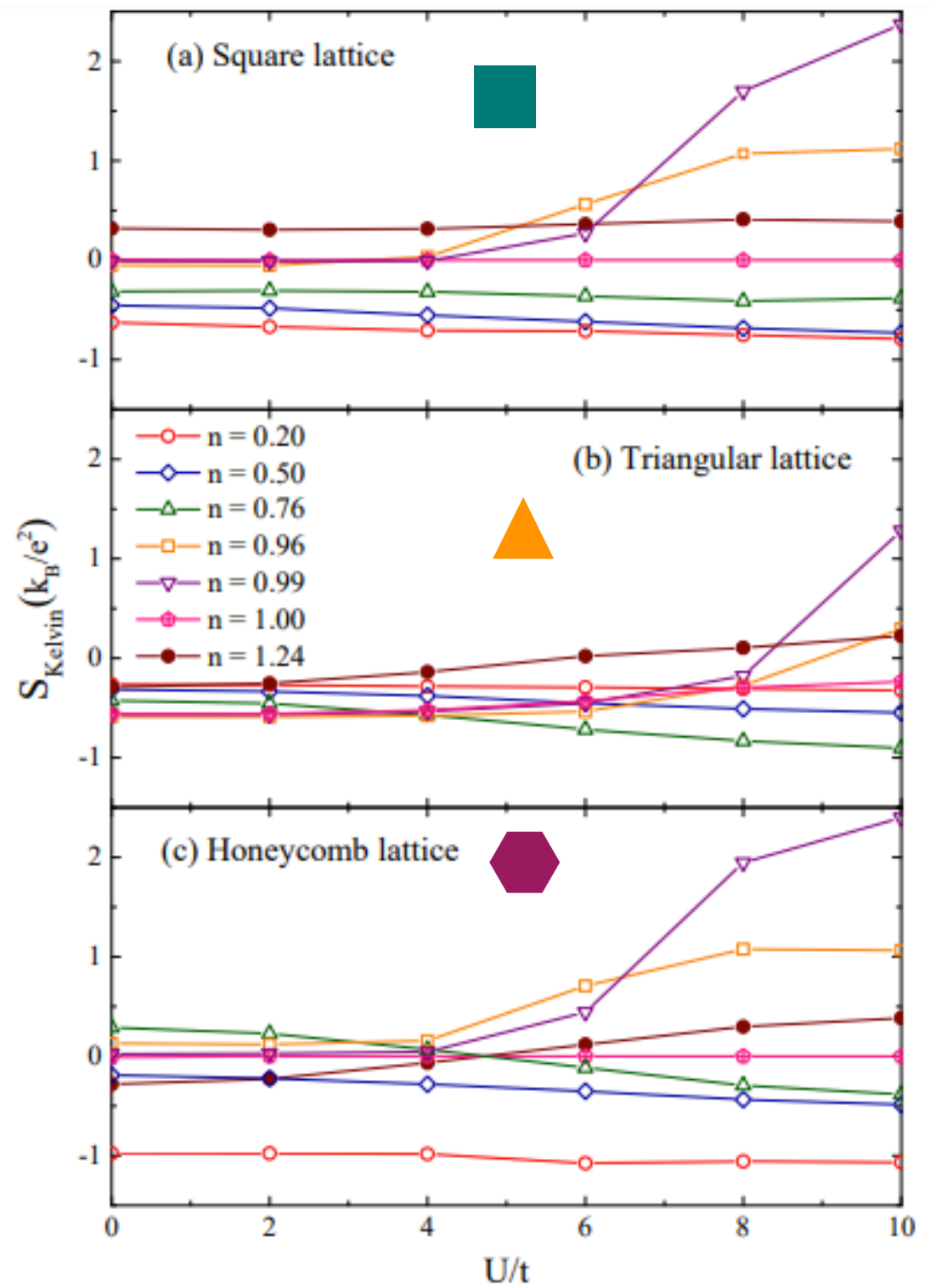
chemical potential ( $\mu$ )



No known analytic solution in 2D

# Effect of correlations

$T/t=0.5$



# Density of States

$$N(\omega = 0, T) = \frac{dn}{d\mu} = n^2 \kappa(T)$$

$$N(\omega = 0) \approx \frac{\beta}{\pi} G(|\mathbf{i} - \mathbf{j}| = 0, \tau = \beta/2)$$

